

## TMUX622x 具有 1.8V 逻辑器件的 36V、低 RON、1:1 (SPST)、2 沟道开关

### 1 特性

- 双电源电压范围：±4.5V 至 ±18 V
- 单电源电压范围：4.5V 至 36 V
- 低导通电阻：2.1  $\Omega$
- -40°C 至 +125°C 工作温度
- 兼容 1.8V 逻辑电平
- 逻辑引脚具有集成的下拉电阻器
- 失效防护逻辑
- 轨到轨运行
- 双向运行

### 2 应用

- 有线网络
- 远程无线电单元
- 患者监护和诊断
- 超声波扫描仪
- 光学测试设备
- 光纤网络
- 工厂自动化和工业控制
- 可编程逻辑控制器 (PLC)
- 模拟输入模块
- 交流充电 (桩) 站
- 半导体测试
- 数据采集系统
- 燃气表
- 流量变送器

### 3 说明

TMUX622x 是互补金属氧化物半导体 (CMOS) 开关，采用双通道 1:1 (SPST) 配置。该器件支持单电源 (4.5V 至 36 V)、双电源 (±4.5V 至 ±18 V) 或非对称电源 (例如， $V_{DD} = 12V$ ， $V_{SS} = -5V$ )。TMUX622x 可在源极 (Sx) 和漏极 (D) 引脚上支持从  $V_{SS}$  到  $V_{DD}$  范围的双向模拟和数字信号。

TMUX622x 可以通过控制 SEL 引脚打开信号路径 1 (S1 至 D1) 或信号路径 2 (S2 至 D2) 来启用或禁用。所有逻辑控制输入均支持 1.8V 到  $V_{DD}$  的逻辑电平，当器件在有效电源电压范围内运行时，可实现 TTL 和 CMOS 逻辑兼容性。失效防护逻辑电路允许先在控制引脚上施加电压，然后在电源引脚上施加电压，从而保护器件免受潜在的损害。

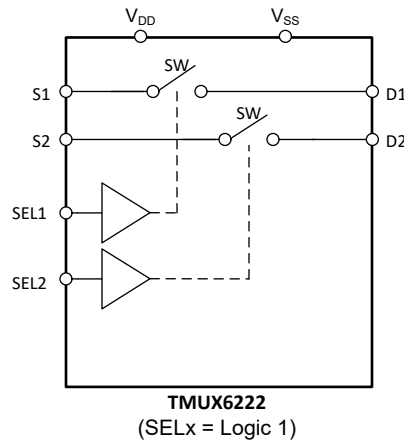
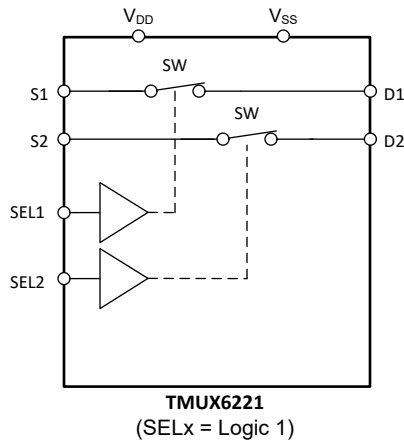
TMUX622x 是精密开关和多路复用器系列器件。这些器件具有非常低的导通和关断漏电流 (50pA)，因此可用于高精度测量应用。

#### 封装信息

| 器件型号                 | 封装 <sup>(1)</sup> | 封装尺寸 <sup>(2)</sup> |
|----------------------|-------------------|---------------------|
| TMUX6221<br>TMUX6222 | DGS (VSSOP, 10)   | 3mm × 4.9mm         |

(1) 有关更多信息，请参阅节 11

(2) 封装尺寸 (长 × 宽) 为标称值，并包括引脚 (如适用)。



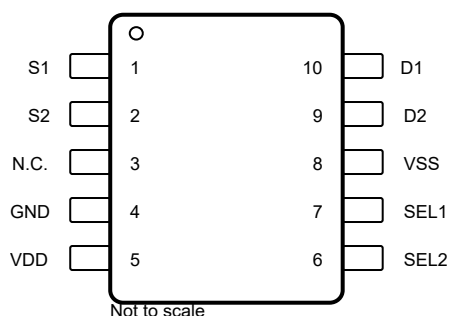
方框图



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## 4 Pin Configuration and Functions



**图 4-1. DGS Package,  
10-Pin VSSOP  
(Top View)**

**表 4-1. Pin Functions**

| PIN             |     | TYPE <sup>(1)</sup> | DESCRIPTION <sup>(2)</sup>                                                                                                                                                                                                                                                      |
|-----------------|-----|---------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME            | NO. |                     |                                                                                                                                                                                                                                                                                 |
| S1              | 1   | I/O                 | Source pin 1. Can be an input or output.                                                                                                                                                                                                                                        |
| S2              | 2   | I/O                 | Source pin 2. Can be an input or output.                                                                                                                                                                                                                                        |
| N.C.            | 3   | —                   | No internal connection. Can be shorted to GND or left floating.                                                                                                                                                                                                                 |
| GND             | 4   | P                   | Ground (0 V) reference                                                                                                                                                                                                                                                          |
| V <sub>DD</sub> | 5   | P                   | Positive power supply. This pin is the most positive power-supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1 $\mu$ F to 10 $\mu$ F between V <sub>DD</sub> and GND.                                                                     |
| SEL2            | 6   | I                   | Logic control input, has internal pull-down resistor. Controls the switch connection. For more information, see <a href="#">节 7.5</a> .                                                                                                                                         |
| SEL1            | 7   | I                   | Logic control input, has internal pull-down resistor. Controls the switch connection. For more information, see <a href="#">节 7.5</a> .                                                                                                                                         |
| V <sub>SS</sub> | 8   | P                   | Negative power supply. This pin is the most negative power-supply potential. In single-supply applications, this pin can be connected to ground. For reliable operation, connect a decoupling capacitor ranging from 0.1 $\mu$ F to 10 $\mu$ F between V <sub>SS</sub> and GND. |
| D2              | 9   | I/O                 | Drain pin 2. Can be an input or output.                                                                                                                                                                                                                                         |
| D1              | 10  | I/O                 | Drain pin 1. Can be an input or output.                                                                                                                                                                                                                                         |

(1) I = input, O = output, I/O = input and output, P = power.

(2) For what to do with unused pins, refer to [节 7.4](#).

## 5 Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1) (2)</sup>

|                       |                                                | MIN            | MAX                            | UNIT |
|-----------------------|------------------------------------------------|----------------|--------------------------------|------|
| $V_{DD} - V_{SS}$     | Supply voltage                                 |                | 38                             | V    |
| $V_{DD}$              |                                                | - 0.5          | 38                             | V    |
| $V_{SS}$              |                                                | - 38           | 0.5                            | V    |
| $V_{SEL}$ or $V_{EN}$ | Logic control input pin voltage (SELx)         | - 0.5          | 38                             | V    |
| $I_{SEL}$ or $I_{EN}$ | Logic control input pin current (SELx)         | - 30           | 30                             | mA   |
| $V_S$ or $V_D$        | Source or drain voltage (Sx, Dx)               | $V_{SS} - 0.5$ | $V_{DD} + 0.5$                 | V    |
| $I_{IK}$              | Diode clamp current <sup>(3)</sup>             | - 30           | 30                             | mA   |
| $I_S$ or $I_D$ (CONT) | Source or drain continuous current (Sx, Dx)    |                | $I_{DC} + 10\%$ <sup>(4)</sup> | mA   |
| $T_A$                 | Ambient temperature                            | - 55           | 150                            | °C   |
| $T_{stg}$             | Storage temperature                            | - 65           | 150                            | °C   |
| $T_J$                 | Junction temperature                           |                | 150                            | °C   |
| $P_{tot}$             | Total power dissipation (VSSOP) <sup>(5)</sup> |                | 450                            | mW   |

- (1) Operation outside the *Absolute Maximum Rating* may cause permanent device damage. *Absolute Maximum Rating* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Condition*. If used outside the *Recommended Operating Condition* but within the *Absolute Maximum Rating*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) All voltages are with respect to ground, unless otherwise specified.
- (3) Pins are diode-clamped to the power-supply rails. Over voltage signals must be voltage and current limited to maximum ratings.
- (4) Refer to *Source or Drain Continuous Current* table for  $I_{DC}$  specifications.
- (5) For VSSOP package:  $P_{tot}$  derates linearly above  $T_A = 70^\circ\text{C}$  by  $6.7\text{mW}/^\circ\text{C}$ .

### 5.2 ESD Ratings

|                 |                         |                                                                                  | VALUE | UNIT |
|-----------------|-------------------------|----------------------------------------------------------------------------------|-------|------|
| <b>TMUX622x</b> |                         |                                                                                  |       |      |
| $V_{(ESD)}$     | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins <sup>(1)</sup>     | ±2000 | V    |
|                 |                         | Charged device model (CDM), per ANSI/ESDA/ JEDEC JS-002, all pins <sup>(2)</sup> | ±500  |      |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 5.3 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | TMUX622x    | UNIT |
|-------------------------------|----------------------------------------------|-------------|------|
|                               |                                              | DGS (VSSOP) |      |
|                               |                                              | 10 PINS     |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 154.3       | °C/W |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 52.9        | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 75.3        | °C/W |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 5.9         | °C/W |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 73.9        | °C/W |
| $R_{\theta JC(bot)}$          | Junction-to-case (bottom) thermal resistance | N/A         | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

### 5.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                                  |                                                                | MIN      | NOM | MAX                     | UNIT |
|----------------------------------|----------------------------------------------------------------|----------|-----|-------------------------|------|
| $V_{DD} - V_{SS}$ <sup>(1)</sup> | Power supply voltage differential                              | 4.5      |     | 36                      | V    |
| $V_{DD}$                         | Positive power supply voltage                                  | 4.5      |     | 36                      | V    |
| $V_S$ or $V_D$                   | Signal path input/output voltage (source or drain pin) (Sx, D) | $V_{SS}$ |     | $V_{DD}$                | V    |
| $V_{SEL}$ or $V_{EN}$            | Address or enable pin voltage                                  | 0        |     | 36                      | V    |
| $I_S$ or $I_D$ (CONT)            | Source or drain continuous current (Sx, D)                     |          |     | $I_{DC}$ <sup>(2)</sup> | mA   |
| $T_A$                            | Ambient temperature                                            | - 40     |     | 125                     | °C   |

(1)  $V_{DD}$  and  $V_{SS}$  can be any value as long as  $4.5\text{ V} \leq (V_{DD} - V_{SS}) \leq 36\text{ V}$ , and the minimum  $V_{DD}$  is met.

(2) Refer to *Source or Drain Continuous Current* table for  $I_{DC}$  specifications.

### 5.5 Source or Drain Continuous Current

at supply voltage of  $V_{DD} \pm 10\%$ ,  $V_{SS} \pm 10\%$  (unless otherwise noted)

| CONTINUOUS CURRENT PER CHANNEL ( $I_{DC}$ ) <sup>(2)</sup> |                                    | $T_A = 25^\circ\text{C}$ | $T_A = 85^\circ\text{C}$ | $T_A = 125^\circ\text{C}$ | UNIT |
|------------------------------------------------------------|------------------------------------|--------------------------|--------------------------|---------------------------|------|
| PACKAGE                                                    | TEST CONDITIONS                    |                          |                          |                           |      |
| DGS (VSSOP)                                                | +36 V Single Supply <sup>(1)</sup> | 360                      | 250                      | 130                       | mA   |
|                                                            | ±15 V Dual Supply                  | 380                      | 260                      | 130                       | mA   |
|                                                            | +12 V Single Supply                | 280                      | 190                      | 100                       | mA   |
|                                                            | ±5 V Dual Supply                   | 240                      | 160                      | 90                        | mA   |

(1) Specified for nominal supply voltage only.

(2) Refer to Total power dissipation ( $P_{tot}$ ) limits in *Absolute Maximum Ratings* table that must be followed with max continuous current specification.

## 5.6 ±15 V Dual Supply: Electrical Characteristics

$V_{DD} = +15\text{ V} \pm 10\%$ ,  $V_{SS} = -15\text{ V} \pm 10\%$ , GND = 0 V (unless otherwise noted)

Typical at  $V_{DD} = +15\text{ V}$ ,  $V_{SS} = -15\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                                |                                           | TEST CONDITIONS                                                                                                                                    | T <sub>A</sub>   | MIN    | TYP     | MAX  | UNIT |
|------------------------------------------|-------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------|------------------|--------|---------|------|------|
| ANALOG SWITCH                            |                                           |                                                                                                                                                    |                  |        |         |      |      |
| R <sub>ON</sub>                          | On-resistance                             | V <sub>S</sub> = - 10 V to +10 V<br>I <sub>D</sub> = - 10 mA                                                                                       | 25°C             |        | 2.1     | 2.9  | Ω    |
|                                          |                                           |                                                                                                                                                    | - 40°C to +85°C  |        |         | 3.8  | Ω    |
|                                          |                                           |                                                                                                                                                    | - 40°C to +125°C |        |         | 4.5  | Ω    |
| Δ R <sub>ON</sub>                        | On-resistance mismatch between channels   | V <sub>S</sub> = - 10 V to +10 V<br>I <sub>D</sub> = - 10 mA                                                                                       | 25°C             |        | 0.05    | 0.25 | Ω    |
|                                          |                                           |                                                                                                                                                    | - 40°C to +85°C  |        |         | 0.3  | Ω    |
|                                          |                                           |                                                                                                                                                    | - 40°C to +125°C |        |         | 0.35 | Ω    |
| R <sub>ON FLAT</sub>                     | On-resistance flatness                    | V <sub>S</sub> = - 10 V to +10 V<br>I <sub>S</sub> = - 10 mA                                                                                       | 25°C             |        | 0.5     | 0.6  | Ω    |
|                                          |                                           |                                                                                                                                                    | - 40°C to +85°C  |        |         | 0.7  | Ω    |
|                                          |                                           |                                                                                                                                                    | - 40°C to +125°C |        |         | 0.85 | Ω    |
| R <sub>ON DRIFT</sub>                    | On-resistance drift                       | V <sub>S</sub> = 0 V, I <sub>S</sub> = - 10 mA                                                                                                     | - 40°C to +125°C |        | 0.01    |      | Ω/°C |
| I <sub>S(OFF)</sub>                      | Source off leakage current <sup>(1)</sup> | V <sub>DD</sub> = 16.5 V, V <sub>SS</sub> = - 16.5 V<br>Switch state is off<br>V <sub>S</sub> = +10 V / - 10 V<br>V <sub>D</sub> = - 10 V / + 10 V | 25°C             | - 0.15 | 0.05    | 0.15 | nA   |
|                                          |                                           |                                                                                                                                                    | - 40°C to +85°C  | - 1.6  |         | 1.6  | nA   |
|                                          |                                           |                                                                                                                                                    | - 40°C to +125°C | - 15   |         | 15   | nA   |
| I <sub>D(OFF)</sub>                      | Drain off leakage current <sup>(1)</sup>  | V <sub>DD</sub> = 16.5 V, V <sub>SS</sub> = - 16.5 V<br>Switch state is off<br>V <sub>S</sub> = +10 V / - 10 V<br>V <sub>D</sub> = - 10 V / + 10 V | 25°C             | - 0.15 | 0.05    | 0.15 | nA   |
|                                          |                                           |                                                                                                                                                    | - 40°C to +85°C  | - 1.6  |         | 1.6  | nA   |
|                                          |                                           |                                                                                                                                                    | - 40°C to +125°C | - 15   |         | 15   | nA   |
| I <sub>S(ON)</sub><br>I <sub>D(ON)</sub> | Channel on leakage current <sup>(2)</sup> | V <sub>DD</sub> = 16.5 V, V <sub>SS</sub> = - 16.5 V<br>Switch state is on<br>V <sub>S</sub> = V <sub>D</sub> = ±10 V                              | 25°C             | - 0.15 | 0.05    | 0.15 | nA   |
|                                          |                                           |                                                                                                                                                    | - 40°C to +85°C  | - 1.6  |         | 1.6  | nA   |
|                                          |                                           |                                                                                                                                                    | - 40°C to +125°C | - 15   |         | 15   | nA   |
| LOGIC INPUTS (SEL / EN pins)             |                                           |                                                                                                                                                    |                  |        |         |      |      |
| V <sub>IH</sub>                          | Logic voltage high                        |                                                                                                                                                    | - 40°C to +125°C | 1.3    |         | 36   | V    |
| V <sub>IL</sub>                          | Logic voltage low                         |                                                                                                                                                    | - 40°C to +125°C | 0      |         | 0.8  | V    |
| I <sub>IH</sub>                          | Input leakage current                     |                                                                                                                                                    | - 40°C to +125°C |        | 1.5     | 2.5  | μA   |
| I <sub>IL</sub>                          | Input leakage current                     |                                                                                                                                                    | - 40°C to +125°C | - 0.1  | - 0.005 |      | μA   |
| C <sub>IN</sub>                          | Logic input capacitance                   |                                                                                                                                                    | - 40°C to +125°C |        | 3.5     |      | pF   |
| POWER SUPPLY                             |                                           |                                                                                                                                                    |                  |        |         |      |      |
| I <sub>DD</sub>                          | V <sub>DD</sub> supply current            | V <sub>DD</sub> = 16.5 V, V <sub>SS</sub> = - 16.5 V<br>Logic inputs = 0 V, 5 V, or V <sub>DD</sub>                                                | 25°C             |        | 30      | 47   | μA   |
|                                          |                                           |                                                                                                                                                    | - 40°C to +85°C  |        |         | 55   | μA   |
|                                          |                                           |                                                                                                                                                    | - 40°C to +125°C |        |         | 72   | μA   |
| I <sub>SS</sub>                          | V <sub>SS</sub> supply current            | V <sub>DD</sub> = 16.5 V, V <sub>SS</sub> = - 16.5 V<br>Logic inputs = 0 V, 5 V, or V <sub>DD</sub>                                                | 25°C             |        | 7       | 15   | μA   |
|                                          |                                           |                                                                                                                                                    | - 40°C to +85°C  |        |         | 20   | μA   |
|                                          |                                           |                                                                                                                                                    | - 40°C to +125°C |        |         | 30   | μA   |

(1) When  $V_S$  is positive,  $V_D$  is negative, or when  $V_S$  is negative,  $V_D$  is positive.

(2) When  $V_S$  is at a voltage potential,  $V_D$  is floating, or when  $V_D$  is at a voltage potential,  $V_S$  is floating.

## 5.7 ±15 V Dual Supply: Switching Characteristics

$V_{DD} = +15\text{ V} \pm 10\%$ ,  $V_{SS} = -15\text{ V} \pm 10\%$ ,  $GND = 0\text{ V}$  (unless otherwise noted)

Typical at  $V_{DD} = +15\text{ V}$ ,  $V_{SS} = -15\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                    |                                           | TEST CONDITIONS                                                                                                                                | $T_A$                                       | MIN | TYP    | MAX | UNIT |
|------------------------------|-------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------|-----|--------|-----|------|
| $t_{ON}$                     | Turn-on time from control input           | $V_S = 10\text{ V}$<br>$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                                                              | $25^\circ\text{C}$                          |     | 145    | 180 | ns   |
|                              |                                           |                                                                                                                                                | $-40^\circ\text{C}$ to $+85^\circ\text{C}$  |     |        | 190 | ns   |
|                              |                                           |                                                                                                                                                | $-40^\circ\text{C}$ to $+125^\circ\text{C}$ |     |        | 200 | ns   |
| $t_{OFF}$                    | Turn-off time from control input          | $V_S = 10\text{ V}$<br>$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                                                              | $25^\circ\text{C}$                          |     | 100    | 180 | ns   |
|                              |                                           |                                                                                                                                                | $-40^\circ\text{C}$ to $+85^\circ\text{C}$  |     |        | 195 | ns   |
|                              |                                           |                                                                                                                                                | $-40^\circ\text{C}$ to $+125^\circ\text{C}$ |     |        | 210 | ns   |
| $t_{ON(VDD)}$                | Device turn on time ( $V_{DD}$ to output) | $V_{DD}$ rise time = $1\ \mu\text{s}$<br>$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                                            | $25^\circ\text{C}$                          |     | 0.19   |     | ms   |
|                              |                                           |                                                                                                                                                | $-40^\circ\text{C}$ to $+85^\circ\text{C}$  |     | 0.2    |     | ms   |
|                              |                                           |                                                                                                                                                | $-40^\circ\text{C}$ to $+125^\circ\text{C}$ |     | 0.2    |     | ms   |
| $t_{PD}$                     | Propagation delay                         | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$                                                                                                       | $25^\circ\text{C}$                          |     | 500    |     | ps   |
| $Q_{INJ}$                    | Charge injection                          | $V_S = 0\text{ V}$ , $C_L = 100\text{ pF}$                                                                                                     | $25^\circ\text{C}$                          |     | -15    |     | pC   |
| $O_{ISO}$                    | Off-isolation                             | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 0\text{ V}$ , $f = 100\text{ kHz}$                                                          | $25^\circ\text{C}$                          |     | -70    |     | dB   |
| $O_{ISO}$                    | Off-isolation                             | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                            | $25^\circ\text{C}$                          |     | -50    |     | dB   |
| $X_{TALK}$                   | Crosstalk                                 | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 0\text{ V}$ , $f = 100\text{ kHz}$                                                          | $25^\circ\text{C}$                          |     | -114   |     | dB   |
| $X_{TALK}$                   | Crosstalk                                 | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                            | $25^\circ\text{C}$                          |     | -93    |     | dB   |
| BW                           | -3dB Bandwidth                            | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 0\text{ V}$                                                                                 | $25^\circ\text{C}$                          |     | 45     |     | MHz  |
| $I_L$                        | Insertion loss                            | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                            | $25^\circ\text{C}$                          |     | -0.18  |     | dB   |
| ACPSRR                       | AC Power Supply Rejection Ratio           | $V_{PP} = 0.62\text{ V}$ on $V_{DD}$ and $V_{SS}$<br>$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ ,<br>$f = 1\text{ MHz}$                          | $25^\circ\text{C}$                          |     | -71    |     | dB   |
| THD+N                        | Total Harmonic Distortion + Noise         | $V_{PP} = 15\text{ V}$ , $V_{BIAS} = 0\text{ V}$<br>$R_L = 10\text{ k}\Omega$ , $C_L = 5\text{ pF}$ ,<br>$f = 20\text{ Hz}$ to $20\text{ kHz}$ | $25^\circ\text{C}$                          |     | 0.0005 |     | %    |
| $C_{S(OFF)}$                 | Source off capacitance                    | $V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                                                                        | $25^\circ\text{C}$                          |     | 25     |     | pF   |
| $C_{D(OFF)}$                 | Drain off capacitance                     | $V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                                                                        | $25^\circ\text{C}$                          |     | 33     |     | pF   |
| $C_{S(ON)}$ ,<br>$C_{D(ON)}$ | On capacitance                            | $V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                                                                        | $25^\circ\text{C}$                          |     | 120    |     | pF   |

## 5.8 36 V Single Supply: Electrical Characteristics

$V_{DD} = +36\text{ V} \pm 10\%$ ,  $V_{SS} = 0\text{ V}$ ,  $GND = 0\text{ V}$  (unless otherwise noted)

Typical at  $V_{DD} = +36\text{ V}$ ,  $V_{SS} = 0\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                                |                                           | TEST CONDITIONS                                                                                                                      | T <sub>A</sub>   | MIN    | TYP     | MAX  | UNIT |
|------------------------------------------|-------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------|------------------|--------|---------|------|------|
| ANALOG SWITCH                            |                                           |                                                                                                                                      |                  |        |         |      |      |
| R <sub>ON</sub>                          | On-resistance                             | V <sub>S</sub> = 0 V to 30 V<br>I <sub>D</sub> = - 10 mA                                                                             | 25°C             |        | 2.5     | 3.2  | Ω    |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  |        |         | 4.2  | Ω    |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C |        |         | 4.9  | Ω    |
| Δ R <sub>ON</sub>                        | On-resistance mismatch between channels   | V <sub>S</sub> = 0 V to 30 V<br>I <sub>D</sub> = - 10 mA                                                                             | 25°C             |        | 0.1     | 0.22 | Ω    |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  |        |         | 0.25 | Ω    |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C |        |         | 0.31 | Ω    |
| R <sub>ON FLAT</sub>                     | On-resistance flatness                    | V <sub>S</sub> = 0 V to 30 V<br>I <sub>S</sub> = - 10 mA                                                                             | 25°C             |        | 0.3     | 1    | Ω    |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  |        |         | 1.5  | Ω    |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C |        |         | 2    | Ω    |
| R <sub>ON DRIFT</sub>                    | On-resistance drift                       | V <sub>S</sub> = 18 V, I <sub>S</sub> = - 10 mA                                                                                      | - 40°C to +125°C |        | 0.009   |      | Ω/°C |
| I <sub>S(OFF)</sub>                      | Source off leakage current <sup>(1)</sup> | V <sub>DD</sub> = 39.6 V, V <sub>SS</sub> = 0 V<br>Switch state is off<br>V <sub>S</sub> = 30 V / 1 V<br>V <sub>D</sub> = 1 V / 30 V | 25°C             | - 0.25 | 0.05    | 0.25 | nA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  | - 3.5  |         | 3.5  | nA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C | - 26   |         | 26   | nA   |
| I <sub>D(OFF)</sub>                      | Drain off leakage current <sup>(1)</sup>  | V <sub>DD</sub> = 39.6 V, V <sub>SS</sub> = 0 V<br>Switch state is off<br>V <sub>S</sub> = 30 V / 1 V<br>V <sub>D</sub> = 1 V / 30 V | 25°C             | - 0.25 | 0.05    | 0.25 | nA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  | - 3.5  |         | 3.5  | nA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C | - 26   |         | 26   | nA   |
| I <sub>S(ON)</sub><br>I <sub>D(ON)</sub> | Channel on leakage current <sup>(2)</sup> | V <sub>DD</sub> = 39.6 V, V <sub>SS</sub> = 0 V<br>Switch state is on<br>V <sub>S</sub> = V <sub>D</sub> = 30 V or 1 V               | 25°C             | - 0.25 | 0.05    | 0.25 | nA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  | - 3.5  |         | 3.5  | nA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C | - 26   |         | 26   | nA   |
| LOGIC INPUTS (SEL / EN pins)             |                                           |                                                                                                                                      |                  |        |         |      |      |
| V <sub>IH</sub>                          | Logic voltage high                        |                                                                                                                                      | - 40°C to +125°C | 1.3    |         | 36   | V    |
| V <sub>IL</sub>                          | Logic voltage low                         |                                                                                                                                      | - 40°C to +125°C | 0      |         | 0.8  | V    |
| I <sub>IH</sub>                          | Input leakage current                     |                                                                                                                                      | - 40°C to +125°C |        | 0.5     | 2.75 | μA   |
| I <sub>IL</sub>                          | Input leakage current                     |                                                                                                                                      | - 40°C to +125°C | - 0.1  | - 0.005 |      | μA   |
| C <sub>IN</sub>                          | Logic input capacitance                   |                                                                                                                                      | - 40°C to +125°C |        | 3.5     |      | pF   |
| POWER SUPPLY                             |                                           |                                                                                                                                      |                  |        |         |      |      |
| I <sub>DD</sub>                          | V <sub>DD</sub> supply current            | V <sub>DD</sub> = 39.6 V, V <sub>SS</sub> = 0 V<br>Logic inputs = 0 V, 5 V, or V <sub>DD</sub>                                       | 25°C             |        | 50      | 60   | μA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  |        |         | 70   | μA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C |        |         | 87   | μA   |

(1) When  $V_S$  is positive,  $V_D$  is negative, or when  $V_S$  is negative,  $V_D$  is positive.

(2) When  $V_S$  is at a voltage potential,  $V_D$  is floating, or when  $V_D$  is at a voltage potential,  $V_S$  is floating.



## 5.9 36 V Single Supply: Switching Characteristics

$V_{DD} = +36\text{ V} \pm 10\%$ ,  $V_{SS} = 0\text{ V}$ ,  $GND = 0\text{ V}$  (unless otherwise noted)

Typical at  $V_{DD} = +36\text{ V}$ ,  $V_{SS} = 0\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                    |                                           | TEST CONDITIONS                                                                                                                                 | $T_A$                                       | MIN | TYP    | MAX | UNIT |
|------------------------------|-------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------|-----|--------|-----|------|
| $t_{ON}$                     | Turn-on time from control input           | $V_S = 18\text{ V}$<br>$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                                                               | $25^\circ\text{C}$                          |     | 110    | 180 | ns   |
|                              |                                           |                                                                                                                                                 | $-40^\circ\text{C}$ to $+85^\circ\text{C}$  |     |        | 190 | ns   |
|                              |                                           |                                                                                                                                                 | $-40^\circ\text{C}$ to $+125^\circ\text{C}$ |     |        | 200 | ns   |
| $t_{OFF}$                    | Turn-off time from control input          | $V_S = 18\text{ V}$<br>$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                                                               | $25^\circ\text{C}$                          |     | 90     | 180 | ns   |
|                              |                                           |                                                                                                                                                 | $-40^\circ\text{C}$ to $+85^\circ\text{C}$  |     |        | 195 | ns   |
|                              |                                           |                                                                                                                                                 | $-40^\circ\text{C}$ to $+125^\circ\text{C}$ |     |        | 200 | ns   |
| $t_{ON(VDD)}$                | Device turn on time ( $V_{DD}$ to output) | $V_{DD}$ rise time = $1\ \mu\text{s}$<br>$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                                             | $25^\circ\text{C}$                          |     | 0.17   |     | ms   |
|                              |                                           |                                                                                                                                                 | $-40^\circ\text{C}$ to $+85^\circ\text{C}$  |     | 0.19   |     | ms   |
|                              |                                           |                                                                                                                                                 | $-40^\circ\text{C}$ to $+125^\circ\text{C}$ |     | 0.19   |     | ms   |
| $t_{PD}$                     | Propagation delay                         | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$                                                                                                        | $25^\circ\text{C}$                          |     | 500    |     | ps   |
| $Q_{INJ}$                    | Charge injection                          | $V_S = 18\text{ V}$ , $C_L = 100\text{ pF}$                                                                                                     | $25^\circ\text{C}$                          |     | -13    |     | pC   |
| $O_{ISO}$                    | Off-isolation                             | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 6\text{ V}$ , $f = 100\text{ kHz}$                                                           | $25^\circ\text{C}$                          |     | -70    |     | dB   |
| $O_{ISO}$                    | Off-isolation                             | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                             | $25^\circ\text{C}$                          |     | -50    |     | dB   |
| $X_{TALK}$                   | Crosstalk                                 | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 6\text{ V}$ , $f = 100\text{ kHz}$                                                           | $25^\circ\text{C}$                          |     | -112   |     | dB   |
| $X_{TALK}$                   | Crosstalk                                 | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                             | $25^\circ\text{C}$                          |     | -93    |     | dB   |
| BW                           | -3dB Bandwidth                            | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 6\text{ V}$                                                                                  | $25^\circ\text{C}$                          |     | 45     |     | MHz  |
| $I_L$                        | Insertion loss                            | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                             | $25^\circ\text{C}$                          |     | -0.19  |     | dB   |
| ACPSRR                       | AC Power Supply Rejection Ratio           | $V_{PP} = 0.62\text{ V}$ on $V_{DD}$ and $V_{SS}$<br>$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ ,<br>$f = 1\text{ MHz}$                           | $25^\circ\text{C}$                          |     | -71    |     | dB   |
| THD+N                        | Total Harmonic Distortion + Noise         | $V_{PP} = 18\text{ V}$ , $V_{BIAS} = 18\text{ V}$<br>$R_L = 10\text{ k}\Omega$ , $C_L = 5\text{ pF}$ ,<br>$f = 20\text{ Hz}$ to $20\text{ kHz}$ | $25^\circ\text{C}$                          |     | 0.0004 |     | %    |
| $C_{S(OFF)}$                 | Source off capacitance                    | $V_S = 18\text{ V}$ , $f = 1\text{ MHz}$                                                                                                        | $25^\circ\text{C}$                          |     | 26     |     | pF   |
| $C_{D(OFF)}$                 | Drain off capacitance                     | $V_S = 18\text{ V}$ , $f = 1\text{ MHz}$                                                                                                        | $25^\circ\text{C}$                          |     | 35     |     | pF   |
| $C_{S(ON)}$ ,<br>$C_{D(ON)}$ | On capacitance                            | $V_S = 18\text{ V}$ , $f = 1\text{ MHz}$                                                                                                        | $25^\circ\text{C}$                          |     | 120    |     | pF   |

## 5.10 12 V Single Supply: Electrical Characteristics

$V_{DD} = +12\text{ V} \pm 10\%$ ,  $V_{SS} = 0\text{ V}$ ,  $GND = 0\text{ V}$  (unless otherwise noted)

Typical at  $V_{DD} = +12\text{ V}$ ,  $V_{SS} = 0\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                                |                                           | TEST CONDITIONS                                                                                                                      | T <sub>A</sub>   | MIN   | TYP     | MAX  | UNIT |
|------------------------------------------|-------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------|------------------|-------|---------|------|------|
| ANALOG SWITCH                            |                                           |                                                                                                                                      |                  |       |         |      |      |
| R <sub>ON</sub>                          | On-resistance                             | V <sub>S</sub> = 0 V to 10 V<br>I <sub>D</sub> = - 10 mA                                                                             | 25°C             |       | 4.6     | 6    | Ω    |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  |       |         | 7.5  | Ω    |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C |       |         | 8.4  | Ω    |
| Δ R <sub>ON</sub>                        | On-resistance mismatch between channels   | V <sub>S</sub> = 0 V to 10 V<br>I <sub>D</sub> = - 10 mA                                                                             | 25°C             |       | 0.08    | 0.2  | Ω    |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  |       |         | 0.32 | Ω    |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C |       |         | 0.35 | Ω    |
| R <sub>ON FLAT</sub>                     | On-resistance flatness                    | V <sub>S</sub> = 0 V to 10 V<br>I <sub>S</sub> = - 10 mA                                                                             | 25°C             |       | 1.2     | 2    | Ω    |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  |       |         | 2.2  | Ω    |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C |       |         | 2.4  | Ω    |
| R <sub>ON DRIFT</sub>                    | On-resistance drift                       | V <sub>S</sub> = 6 V, I <sub>S</sub> = - 10 mA                                                                                       | - 40°C to +125°C |       | 0.017   |      | Ω/°C |
| I <sub>S(OFF)</sub>                      | Source off leakage current <sup>(1)</sup> | V <sub>DD</sub> = 13.2 V, V <sub>SS</sub> = 0 V<br>Switch state is off<br>V <sub>S</sub> = 10 V / 1 V<br>V <sub>D</sub> = 1 V / 10 V | 25°C             | - 0.5 | 0.05    | 0.5  | nA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  | - 2   |         | 2    | nA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C | - 12  |         | 12   | nA   |
| I <sub>D(OFF)</sub>                      | Drain off leakage current <sup>(1)</sup>  | V <sub>DD</sub> = 13.2 V, V <sub>SS</sub> = 0 V<br>Switch state is off<br>V <sub>S</sub> = 10 V / 1 V<br>V <sub>D</sub> = 1 V / 10 V | 25°C             | - 0.5 | 0.05    | 0.5  | nA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  | - 2   |         | 2    | nA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C | - 12  |         | 12   | nA   |
| I <sub>S(ON)</sub><br>I <sub>D(ON)</sub> | Channel on leakage current <sup>(2)</sup> | V <sub>DD</sub> = 13.2 V, V <sub>SS</sub> = 0 V<br>Switch state is on<br>V <sub>S</sub> = V <sub>D</sub> = 10 V or 1 V               | 25°C             | - 0.5 | 0.05    | 0.5  | nA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  | - 2   |         | 2    | nA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C | - 12  |         | 12   | nA   |
| LOGIC INPUTS (SEL / EN pins)             |                                           |                                                                                                                                      |                  |       |         |      |      |
| V <sub>IH</sub>                          | Logic voltage high                        |                                                                                                                                      | - 40°C to +125°C | 1.3   |         | 36   | V    |
| V <sub>IL</sub>                          | Logic voltage low                         |                                                                                                                                      | - 40°C to +125°C | 0     |         | 0.8  | V    |
| I <sub>IH</sub>                          | Input leakage current                     |                                                                                                                                      | - 40°C to +125°C |       | 0.5     | 2.5  | μA   |
| I <sub>IL</sub>                          | Input leakage current                     |                                                                                                                                      | - 40°C to +125°C | - 0.1 | - 0.005 |      | μA   |
| C <sub>IN</sub>                          | Logic input capacitance                   |                                                                                                                                      | - 40°C to +125°C |       | 3.5     |      | pF   |
| POWER SUPPLY                             |                                           |                                                                                                                                      |                  |       |         |      |      |
| I <sub>DD</sub>                          | V <sub>DD</sub> supply current            | V <sub>DD</sub> = 13.2 V, V <sub>SS</sub> = 0 V<br>Logic inputs = 0 V, 5 V, or V <sub>DD</sub>                                       | 25°C             |       | 30      | 40   | μA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +85°C  |       |         | 50   | μA   |
|                                          |                                           |                                                                                                                                      | - 40°C to +125°C |       |         | 62   | μA   |

(1) When  $V_S$  is positive,  $V_D$  is negative, or when  $V_S$  is negative,  $V_D$  is positive.

(2) When  $V_S$  is at a voltage potential,  $V_D$  is floating, or when  $V_D$  is at a voltage potential,  $V_S$  is floating.

## 5.11 12 V Single Supply: Switching Characteristics

$V_{DD} = +12\text{ V} \pm 10\%$ ,  $V_{SS} = 0\text{ V}$ ,  $GND = 0\text{ V}$  (unless otherwise noted)

Typical at  $V_{DD} = +12\text{ V}$ ,  $V_{SS} = 0\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                    |                                              | TEST CONDITIONS                                                                                                                               | $T_A$                                       | MIN | TYP    | MAX | UNIT |
|------------------------------|----------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------|-----|--------|-----|------|
| $t_{ON}$                     | Turn-on time from control input              | $V_S = 8\text{ V}$<br>$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                                                              | $25^\circ\text{C}$                          |     | 120    | 180 | ns   |
|                              |                                              |                                                                                                                                               | $-40^\circ\text{C}$ to $+85^\circ\text{C}$  |     |        | 210 | ns   |
|                              |                                              |                                                                                                                                               | $-40^\circ\text{C}$ to $+125^\circ\text{C}$ |     |        | 230 | ns   |
| $t_{OFF}$                    | Turn-off time from control input             | $V_S = 8\text{ V}$<br>$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                                                              | $25^\circ\text{C}$                          |     | 130    | 210 | ns   |
|                              |                                              |                                                                                                                                               | $-40^\circ\text{C}$ to $+85^\circ\text{C}$  |     |        | 235 | ns   |
|                              |                                              |                                                                                                                                               | $-40^\circ\text{C}$ to $+125^\circ\text{C}$ |     |        | 250 | ns   |
| $t_{ON(VDD)}$                | Device turn on time<br>( $V_{DD}$ to output) | $V_{DD}$ rise time = $1\ \mu\text{s}$<br>$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                                           | $25^\circ\text{C}$                          |     | 0.19   |     | ms   |
|                              |                                              |                                                                                                                                               | $-40^\circ\text{C}$ to $+85^\circ\text{C}$  |     | 0.2    |     | ms   |
|                              |                                              |                                                                                                                                               | $-40^\circ\text{C}$ to $+125^\circ\text{C}$ |     | 0.2    |     | ms   |
| $t_{PD}$                     | Propagation delay                            | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$                                                                                                      | $25^\circ\text{C}$                          |     | 500    |     | ps   |
| $Q_{INJ}$                    | Charge injection                             | $V_S = 6\text{ V}$ , $C_L = 100\text{ pF}$                                                                                                    | $25^\circ\text{C}$                          |     | -6     |     | pC   |
| $O_{ISO}$                    | Off-isolation                                | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 6\text{ V}$ , $f = 100\text{ kHz}$                                                         | $25^\circ\text{C}$                          |     | -70    |     | dB   |
| $O_{ISO}$                    | Off-isolation                                | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                           | $25^\circ\text{C}$                          |     | -50    |     | dB   |
| $X_{TALK}$                   | Crosstalk                                    | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 6\text{ V}$ , $f = 100\text{ kHz}$                                                         | $25^\circ\text{C}$                          |     | -112   |     | dB   |
| $X_{TALK}$                   | Crosstalk                                    | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                           | $25^\circ\text{C}$                          |     | -93    |     | dB   |
| BW                           | -3dB Bandwidth                               | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 6\text{ V}$                                                                                | $25^\circ\text{C}$                          |     | 60     |     | MHz  |
| $I_L$                        | Insertion loss                               | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                           | $25^\circ\text{C}$                          |     | -0.3   |     | dB   |
| ACPSRR                       | AC Power Supply Rejection Ratio              | $V_{PP} = 0.62\text{ V}$ on $V_{DD}$ and $V_{SS}$<br>$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ ,<br>$f = 1\text{ MHz}$                         | $25^\circ\text{C}$                          |     | -76    |     | dB   |
| THD+N                        | Total Harmonic Distortion + Noise            | $V_{PP} = 6\text{ V}$ , $V_{BIAS} = 6\text{ V}$<br>$R_L = 10\text{ k}\Omega$ , $C_L = 5\text{ pF}$ ,<br>$f = 20\text{ Hz}$ to $20\text{ kHz}$ | $25^\circ\text{C}$                          |     | 0.0009 |     | %    |
| $C_{S(OFF)}$                 | Source off capacitance                       | $V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                                                                       | $25^\circ\text{C}$                          |     | 30     |     | pF   |
| $C_{D(OFF)}$                 | Drain off capacitance                        | $V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                                                                       | $25^\circ\text{C}$                          |     | 38     |     | pF   |
| $C_{S(ON)}$ ,<br>$C_{D(ON)}$ | On capacitance                               | $V_S = 6\text{ V}$ , $f = 1\text{ MHz}$                                                                                                       | $25^\circ\text{C}$                          |     | 110    |     | pF   |

## 5.12 ±5 V Dual Supply: Electrical Characteristics

$V_{DD} = +5\text{ V} \pm 10\%$ ,  $V_{SS} = -5\text{ V} \pm 10\%$ , GND = 0 V (unless otherwise noted)

Typical at  $V_{DD} = +5\text{ V}$ ,  $V_{SS} = -5\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                                |                                           | TEST CONDITIONS                                                                                                                                       | T <sub>A</sub>   | MIN    | TYP     | MAX  | UNIT |
|------------------------------------------|-------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------|------------------|--------|---------|------|------|
| ANALOG SWITCH                            |                                           |                                                                                                                                                       |                  |        |         |      |      |
| R <sub>ON</sub>                          | On-resistance                             | V <sub>DD</sub> = +4.5 V, V <sub>SS</sub> = - 4.5 V<br>V <sub>S</sub> = - 4.5 V to +4.5 V<br>I <sub>D</sub> = - 10 mA                                 | 25°C             |        | 4       | 7.2  | Ω    |
|                                          |                                           |                                                                                                                                                       | - 40°C to +85°C  |        |         | 8.6  | Ω    |
|                                          |                                           |                                                                                                                                                       | - 40°C to +125°C |        |         | 10   | Ω    |
| Δ R <sub>ON</sub>                        | On-resistance mismatch between channels   | V <sub>S</sub> = - 4.5 V to +4.5 V<br>I <sub>D</sub> = - 10 mA                                                                                        | 25°C             |        | 0.1     | 0.3  | Ω    |
|                                          |                                           |                                                                                                                                                       | - 40°C to +85°C  |        |         | 0.35 | Ω    |
|                                          |                                           |                                                                                                                                                       | - 40°C to +125°C |        |         | 0.4  | Ω    |
| R <sub>ON FLAT</sub>                     | On-resistance flatness                    | V <sub>S</sub> = - 4.5 V to +4.5 V<br>I <sub>D</sub> = - 10 mA                                                                                        | 25°C             |        | 1.3     | 2.2  | Ω    |
|                                          |                                           |                                                                                                                                                       | - 40°C to +85°C  |        |         | 2.5  | Ω    |
|                                          |                                           |                                                                                                                                                       | - 40°C to +125°C |        |         | 2.8  | Ω    |
| R <sub>ON DRIFT</sub>                    | On-resistance drift                       | V <sub>S</sub> = 0 V, I <sub>S</sub> = - 10 mA                                                                                                        | - 40°C to +125°C |        | 0.019   |      | Ω/°C |
| I <sub>S(OFF)</sub>                      | Source off leakage current <sup>(1)</sup> | V <sub>DD</sub> = +5.5 V, V <sub>SS</sub> = - 5.5 V<br>Switch state is off<br>V <sub>S</sub> = +4.5 V / - 4.5 V<br>V <sub>D</sub> = - 4.5 V / + 4.5 V | 25°C             | - 0.25 | 0.05    | 0.25 | nA   |
|                                          |                                           |                                                                                                                                                       | - 40°C to +85°C  | - 1    |         | 1    | nA   |
|                                          |                                           |                                                                                                                                                       | - 40°C to +125°C | - 12   |         | 12   | nA   |
| I <sub>D(OFF)</sub>                      | Drain off leakage current <sup>(1)</sup>  | V <sub>DD</sub> = +5.5 V, V <sub>SS</sub> = - 5.5 V<br>Switch state is off<br>V <sub>S</sub> = +4.5 V / - 4.5 V<br>V <sub>D</sub> = - 4.5 V / + 4.5 V | 25°C             | - 0.25 | 0.05    | 0.25 | nA   |
|                                          |                                           |                                                                                                                                                       | - 40°C to +85°C  | - 1    |         | 1    | nA   |
|                                          |                                           |                                                                                                                                                       | - 40°C to +125°C | - 12   |         | 12   | nA   |
| I <sub>S(ON)</sub><br>I <sub>D(ON)</sub> | Channel on leakage current <sup>(2)</sup> | V <sub>DD</sub> = +5.5 V, V <sub>SS</sub> = - 5.5 V<br>Switch state is on<br>V <sub>S</sub> = V <sub>D</sub> = ±4.5 V                                 | 25°C             | - 0.25 | 0.05    | 0.25 | nA   |
|                                          |                                           |                                                                                                                                                       | - 40°C to +85°C  | - 1    |         | 1    | nA   |
|                                          |                                           |                                                                                                                                                       | - 40°C to +125°C | - 12   |         | 12   | nA   |
| LOGIC INPUTS (SEL / EN pins)             |                                           |                                                                                                                                                       |                  |        |         |      |      |
| V <sub>IH</sub>                          | Logic voltage high                        |                                                                                                                                                       | - 40°C to +125°C | 1.3    |         | 36   | V    |
| V <sub>IL</sub>                          | Logic voltage low                         |                                                                                                                                                       | - 40°C to +125°C | 0      |         | 0.8  | V    |
| I <sub>IH</sub>                          | Input leakage current                     |                                                                                                                                                       | - 40°C to +125°C |        | 0.5     | 2    | μA   |
| I <sub>IL</sub>                          | Input leakage current                     |                                                                                                                                                       | - 40°C to +125°C | - 0.1  | - 0.005 |      | μA   |
| C <sub>IN</sub>                          | Logic input capacitance                   |                                                                                                                                                       | - 40°C to +125°C |        | 3.5     |      | pF   |
| POWER SUPPLY                             |                                           |                                                                                                                                                       |                  |        |         |      |      |
| I <sub>DD</sub>                          | V <sub>DD</sub> supply current            | V <sub>DD</sub> = +5.5 V, V <sub>SS</sub> = - 5.5 V<br>Logic inputs = 0 V, 5 V, or V <sub>DD</sub>                                                    | 25°C             |        | 28      | 40   | μA   |
|                                          |                                           |                                                                                                                                                       | - 40°C to +85°C  |        |         | 50   | μA   |
|                                          |                                           |                                                                                                                                                       | - 40°C to +125°C |        |         | 60   | μA   |
| I <sub>SS</sub>                          | V <sub>SS</sub> supply current            | V <sub>DD</sub> = +5.5 V, V <sub>SS</sub> = - 5.5 V<br>Logic inputs = 0 V, 5 V, or V <sub>DD</sub>                                                    | 25°C             |        | 5       | 10   | μA   |
|                                          |                                           |                                                                                                                                                       | - 40°C to +85°C  |        |         | 12   | μA   |
|                                          |                                           |                                                                                                                                                       | - 40°C to +125°C |        |         | 21   | μA   |

(1) When  $V_S$  is positive,  $V_D$  is negative, or when  $V_S$  is negative,  $V_D$  is positive.

(2) When  $V_S$  is at a voltage potential,  $V_D$  is floating, or when  $V_D$  is at a voltage potential,  $V_S$  is floating.

### 5.13 $\pm 5$ V Dual Supply: Switching Characteristics

$V_{DD} = +5\text{ V} \pm 10\%$ ,  $V_{SS} = -5\text{ V} \pm 10\%$ ,  $GND = 0\text{ V}$  (unless otherwise noted)

Typical at  $V_{DD} = +5\text{ V}$ ,  $V_{SS} = -5\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                    |                                              | TEST CONDITIONS                                                                                                                               | $T_A$                                       | MIN | TYP   | MAX | UNIT |
|------------------------------|----------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------|-----|-------|-----|------|
| $t_{ON}$                     | Turn-on time from control input              | $V_S = 3\text{ V}$<br>$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                                                              | $25^\circ\text{C}$                          |     | 220   | 300 | ns   |
|                              |                                              |                                                                                                                                               | $-40^\circ\text{C}$ to $+85^\circ\text{C}$  |     |       | 350 | ns   |
|                              |                                              |                                                                                                                                               | $-40^\circ\text{C}$ to $+125^\circ\text{C}$ |     |       | 380 | ns   |
| $t_{OFF}$                    | Turn-off time from control input             | $V_S = 3\text{ V}$<br>$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                                                              | $25^\circ\text{C}$                          |     | 210   | 280 | ns   |
|                              |                                              |                                                                                                                                               | $-40^\circ\text{C}$ to $+85^\circ\text{C}$  |     |       | 330 | ns   |
|                              |                                              |                                                                                                                                               | $-40^\circ\text{C}$ to $+125^\circ\text{C}$ |     |       | 350 | ns   |
| $t_{ON(VDD)}$                | Device turn on time<br>( $V_{DD}$ to output) | $V_{DD}$ rise time = $1\ \mu\text{s}$<br>$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$                                                           | $25^\circ\text{C}$                          |     | 0.19  |     | ms   |
|                              |                                              |                                                                                                                                               | $-40^\circ\text{C}$ to $+85^\circ\text{C}$  |     | 0.19  |     | ms   |
|                              |                                              |                                                                                                                                               | $-40^\circ\text{C}$ to $+125^\circ\text{C}$ |     | 0.19  |     | ms   |
| $t_{PD}$                     | Propagation delay                            | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$                                                                                                      | $25^\circ\text{C}$                          |     | 500   |     | ps   |
| $Q_{INJ}$                    | Charge injection                             | $V_S = 0\text{ V}$ , $C_L = 100\text{ pF}$                                                                                                    | $25^\circ\text{C}$                          |     | -5    |     | pC   |
| $O_{ISO}$                    | Off-isolation                                | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 0\text{ V}$ , $f = 100\text{ kHz}$                                                         | $25^\circ\text{C}$                          |     | -70   |     | dB   |
| $O_{ISO}$                    | Off-isolation                                | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                           | $25^\circ\text{C}$                          |     | -50   |     | dB   |
| $X_{TALK}$                   | Crosstalk                                    | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 0\text{ V}$ , $f = 100\text{ kHz}$                                                         | $25^\circ\text{C}$                          |     | -117  |     | dB   |
| $X_{TALK}$                   | Crosstalk                                    | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                           | $25^\circ\text{C}$                          |     | -94   |     | dB   |
| BW                           | -3dB Bandwidth                               | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 0\text{ V}$                                                                                | $25^\circ\text{C}$                          |     | 67    |     | MHz  |
| $I_L$                        | Insertion loss                               | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$<br>$V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                           | $25^\circ\text{C}$                          |     | -0.35 |     | dB   |
| ACPSRR                       | AC Power Supply Rejection Ratio              | $V_{PP} = 0.62\text{ V}$ on $V_{DD}$ and $V_{SS}$<br>$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ ,<br>$f = 1\text{ MHz}$                         | $25^\circ\text{C}$                          |     | -76   |     | dB   |
| THD+N                        | Total Harmonic Distortion + Noise            | $V_{PP} = 5\text{ V}$ , $V_{BIAS} = 0\text{ V}$<br>$R_L = 10\text{ k}\Omega$ , $C_L = 5\text{ pF}$ ,<br>$f = 20\text{ Hz}$ to $20\text{ kHz}$ | $25^\circ\text{C}$                          |     | 0.001 |     | %    |
| $C_{S(OFF)}$                 | Source off capacitance                       | $V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                                                                       | $25^\circ\text{C}$                          |     | 30    |     | pF   |
| $C_{D(OFF)}$                 | Drain off capacitance                        | $V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                                                                       | $25^\circ\text{C}$                          |     | 40    |     | pF   |
| $C_{S(ON)}$ ,<br>$C_{D(ON)}$ | On capacitance                               | $V_S = 0\text{ V}$ , $f = 1\text{ MHz}$                                                                                                       | $25^\circ\text{C}$                          |     | 120   |     | pF   |

## 5.14 Typical Characteristics

at  $T_A = 25^\circ\text{C}$

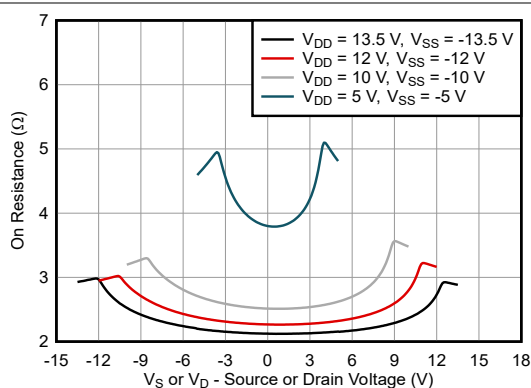


图 5-1. On-Resistance vs Source or Drain Voltage - Dual Supply

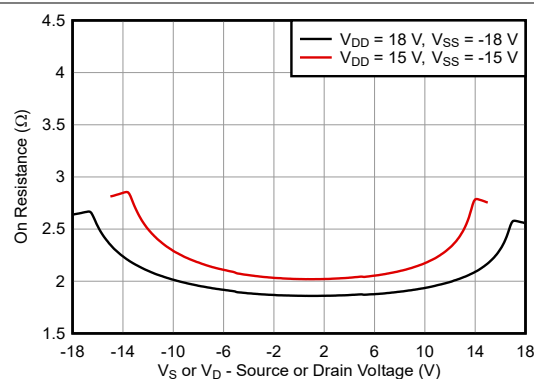


图 5-2. On-Resistance vs Source or Drain Voltage - Dual Supply

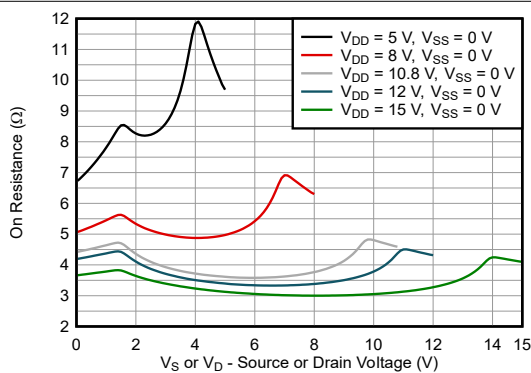


图 5-3. On-Resistance vs Source or Drain Voltage - Single Supply

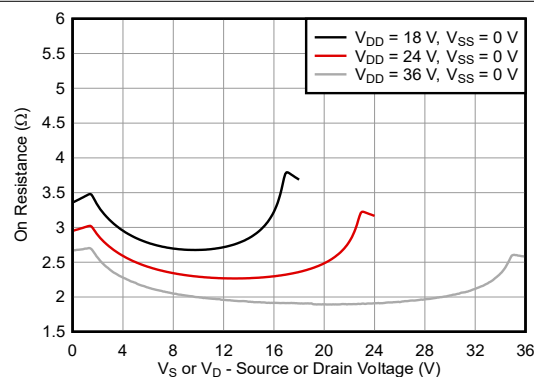


图 5-4. On-Resistance vs Source or Drain Voltage - Single Supply

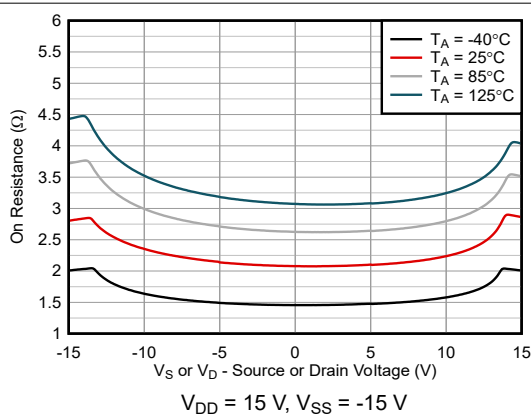


图 5-5. On-Resistance vs Temperature

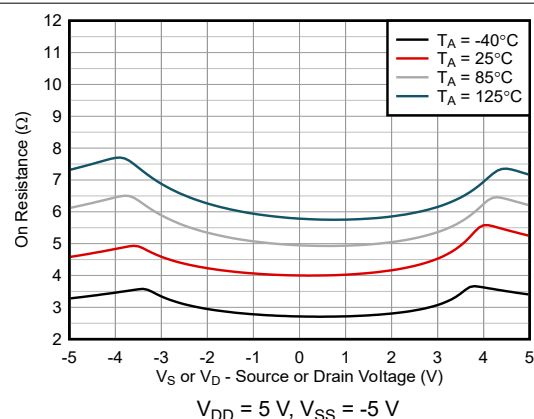


图 5-6. On-Resistance vs Temperature

## 5.14 Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$

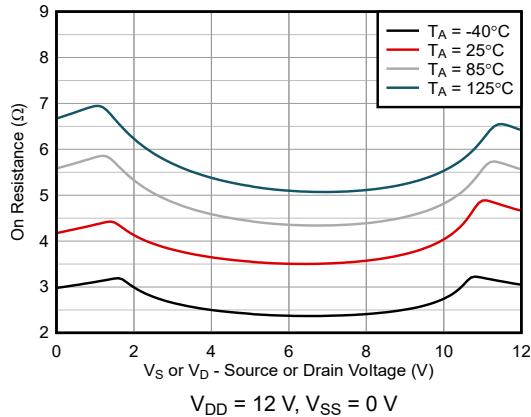


图 5-7. On-Resistance vs Temperature

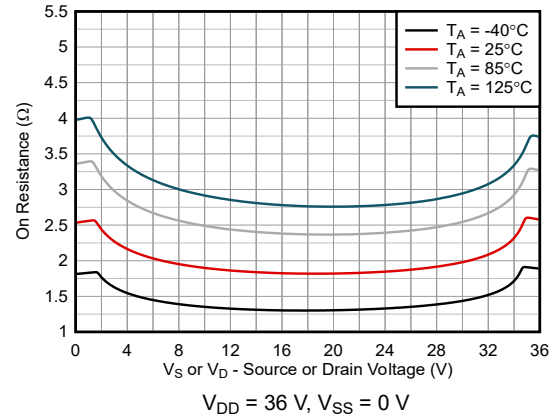


图 5-8. On-Resistance vs Temperature

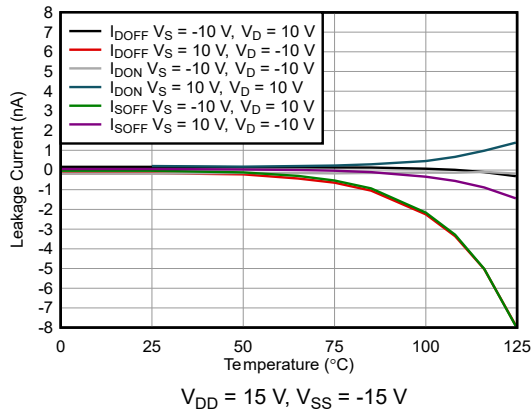


图 5-9. Leakage Current vs Temperature

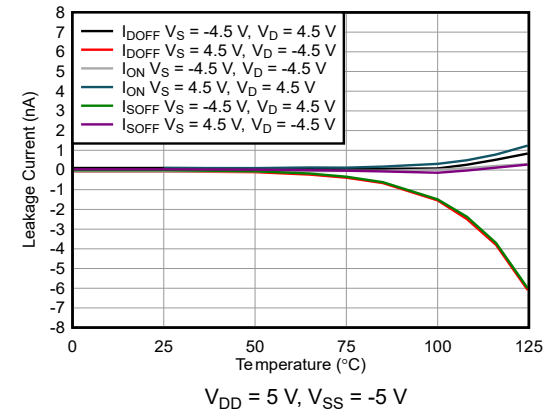


图 5-10. Leakage Current vs Temperature

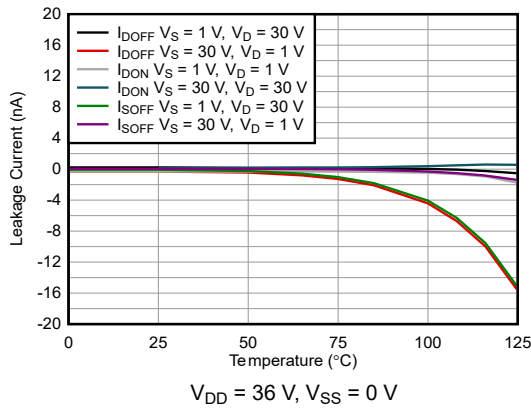


图 5-11. Leakage Current vs Temperature

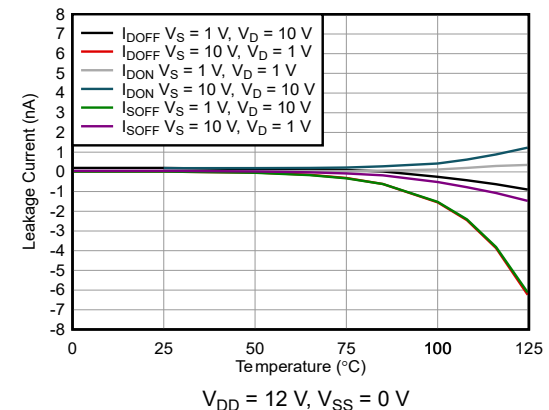


图 5-12. Leakage Current vs Temperature

## 5.14 Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$

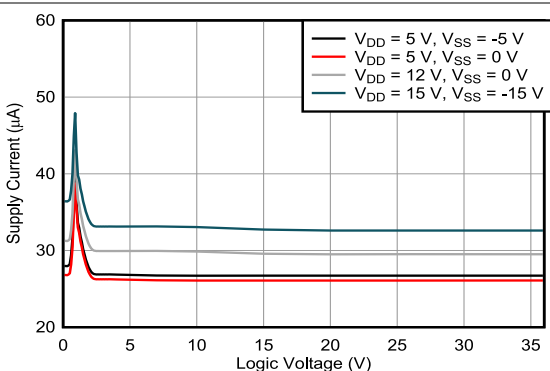


图 5-13. Supply Current vs Logic Voltage

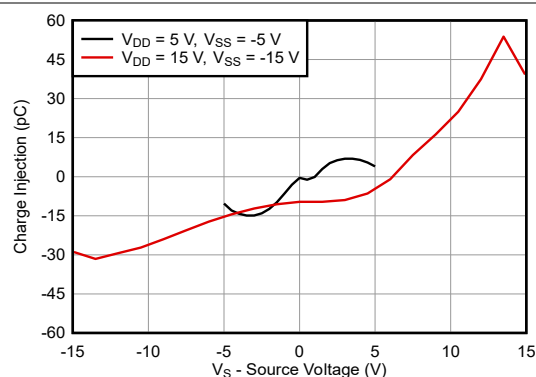


图 5-14. Charge Injection vs Source Voltage - Dual Supplies

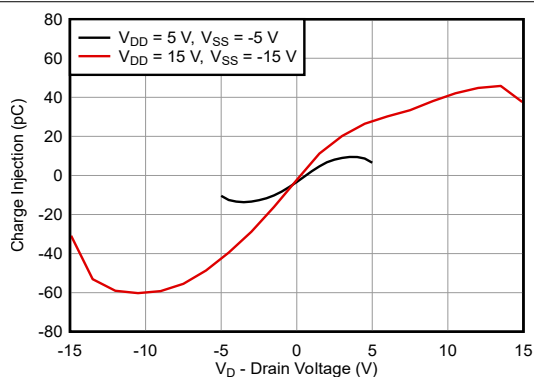


图 5-15. Charge Injection vs Drain Voltage - Dual Supplies

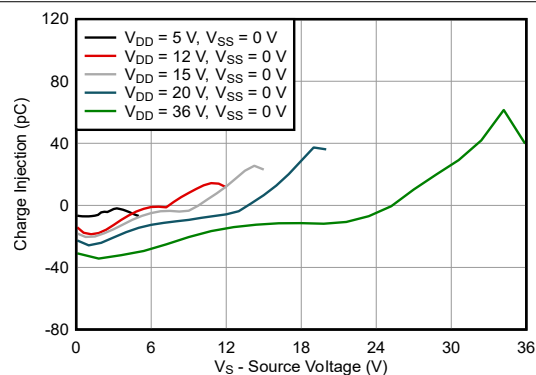


图 5-16. Charge Injection vs Source Voltage - Single Supplies

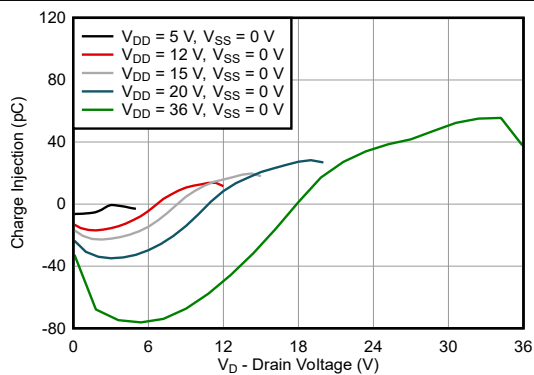


图 5-17. Charge Injection vs Drain Voltage - Single Supplies

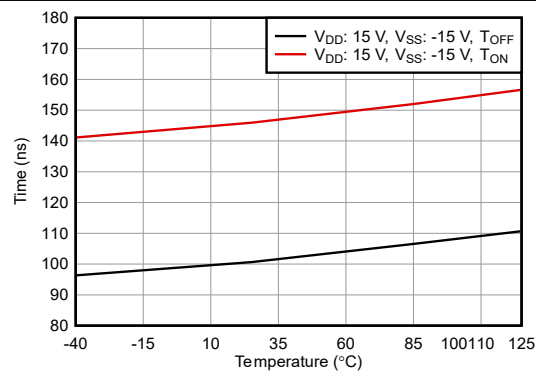


图 5-18.  $T_{ON}$  and  $T_{OFF}$  vs Temperature



## 5.14 Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$

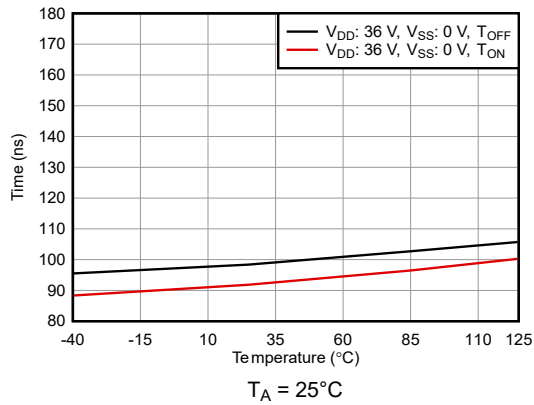


图 5-19.  $T_{ON}$  and  $T_{OFF}$  vs Temperature

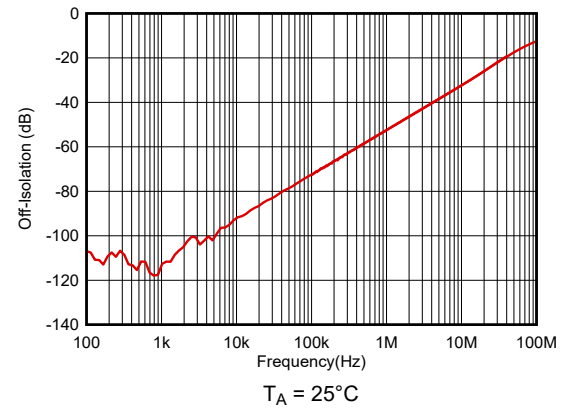


图 5-20. Off-Isolation vs Frequency

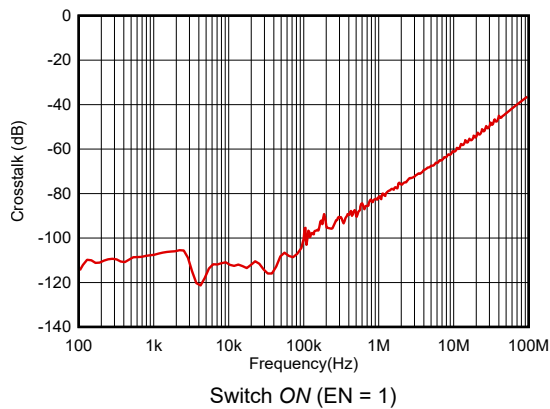


图 5-21. Crosstalk vs Frequency

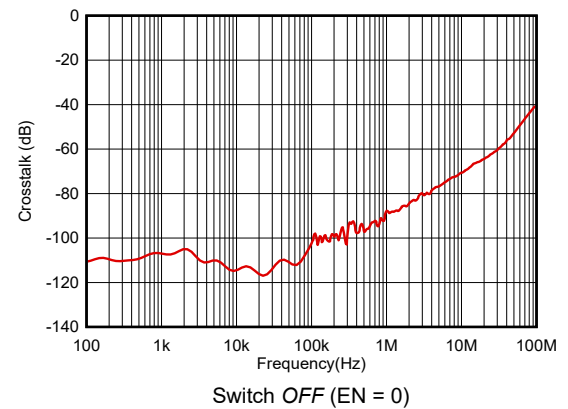


图 5-22. Crosstalk vs Frequency

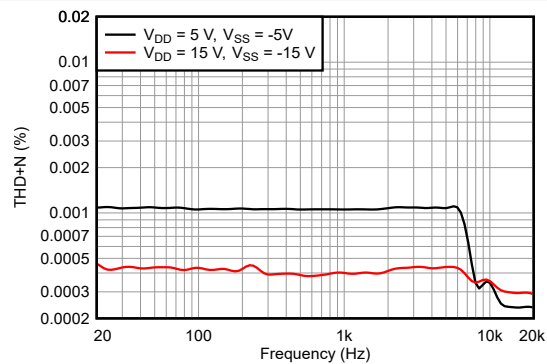


图 5-23. THD+N vs Frequency (Dual Supplies)

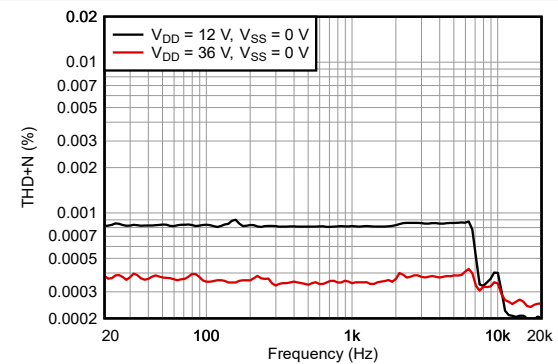


图 5-24. THD+N vs Frequency (Single Supplies)

## 5.14 Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$

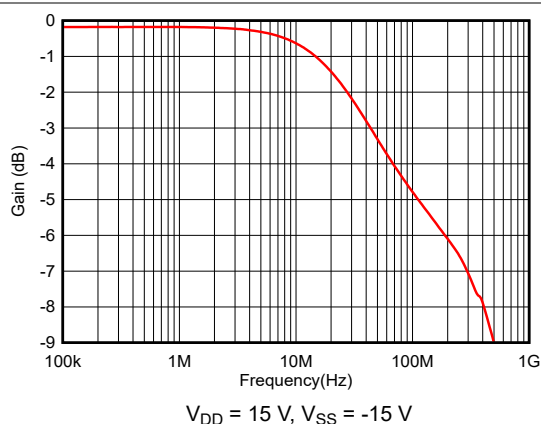


图 5-25. On Response vs Frequency

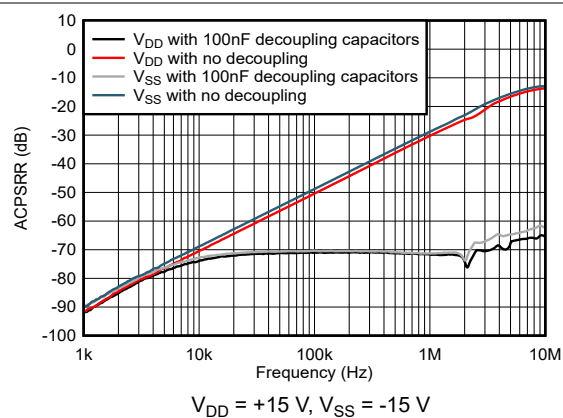


图 5-26. ACPSRR vs Frequency

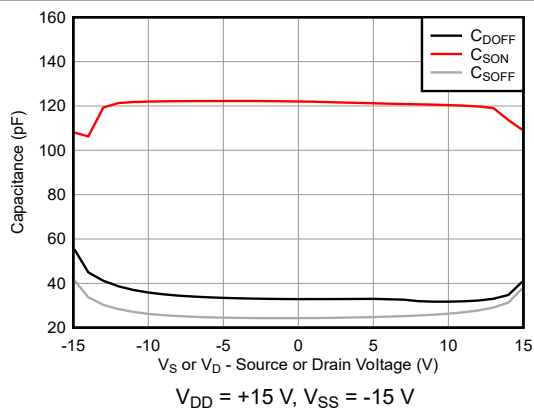


图 5-27. Capacitance vs Source Voltage or Drain Voltage

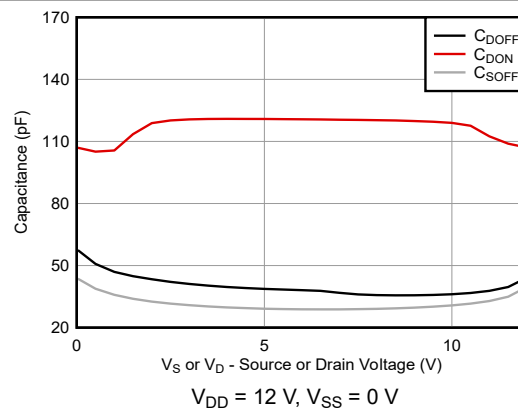


图 5-28. Capacitance vs Source Voltage or Drain Voltage

## 6 Parameter Measurement Information

### 6.1 On-Resistance

The on-resistance of a device is the ohmic resistance between the source (Sx) and drain (D) pins of the device. The on-resistance varies with input voltage and supply voltage. The symbol  $R_{ON}$  is used to denote on-resistance. 图 6-1 shows the measurement setup used to measure  $R_{ON}$ . Voltage (V) and current ( $I_{SD}$ ) are measured using the following setup, where  $R_{ON}$  is computed as  $R_{ON} = V / I_{SD}$ .

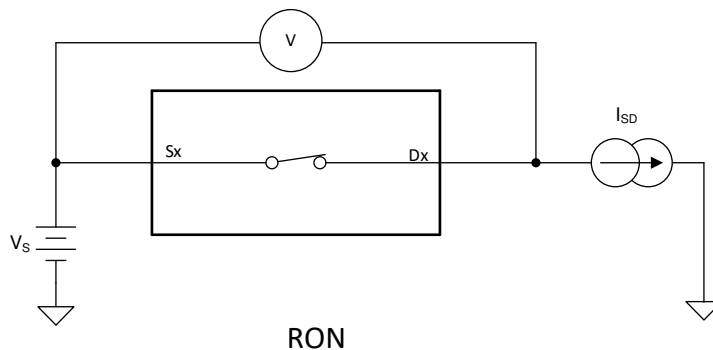


图 6-1. On-Resistance

### 6.2 Off-Leakage Current

There are two types of leakage currents associated with a switch during the off state:

1. Source off-leakage current.
2. Drain off-leakage current.

Source leakage current is defined as the leakage current flowing into or out of the source pin when the switch is off. This current is denoted by the symbol  $I_{S(OFF)}$ .

Drain leakage current is defined as the leakage current flowing into or out of the drain pin when the switch is off. This current is denoted by the symbol  $I_{D(OFF)}$ .

图 6-2 shows the setup used to measure both off-leakage currents.

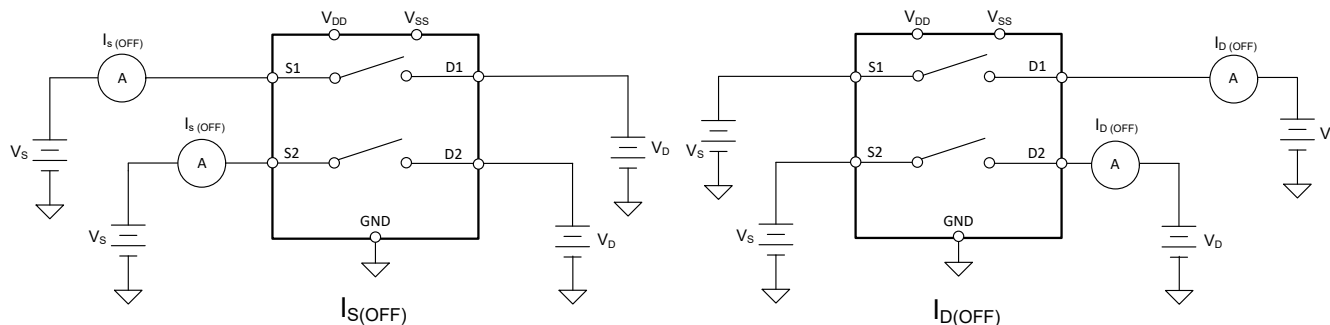


图 6-2. Off-Leakage Measurement Setup

### 6.3 On-Leakage Current

Source on-leakage current is defined as the leakage current flowing into or out of the source pin when the switch is on. This current is denoted by the symbol  $I_{S(ON)}$ .

Drain on-leakage current is defined as the leakage current flowing into or out of the drain pin when the switch is on. This current is denoted by the symbol  $I_{D(ON)}$ .

Either the source pin or drain pin is left floating during the measurement. 图 6-3 shows the circuit used for measuring the on-leakage current, denoted by  $I_{S(ON)}$  or  $I_{D(ON)}$ .

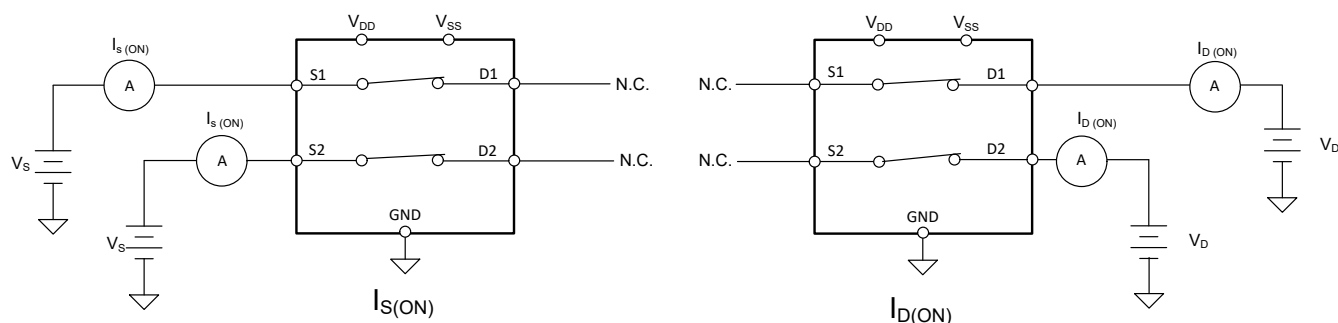


图 6-3. On-Leakage Measurement Setup

### 6.4 $t_{ON(EN)}$ and $t_{OFF(EN)}$

Turn-on time is defined as the time taken by the output of the device to rise to 90% after the enable has risen past the logic threshold. The 90% measurement is utilized to provide the timing of the device. System level timing can then account for the time constant added from the load resistance and load capacitance. 图 6-4 shows the setup used to measure turn-on time, denoted by the symbol  $t_{ON(EN)}$ .

Turn-off time is defined as the time taken by the output of the device to fall to 10% after the enable has fallen past the logic threshold. The 10% measurement is utilized to provide the timing of the device. System level timing can then account for the time constant added from the load resistance and load capacitance. 图 6-4 shows the setup used to measure turn-off time, denoted by the symbol  $t_{OFF(EN)}$ .

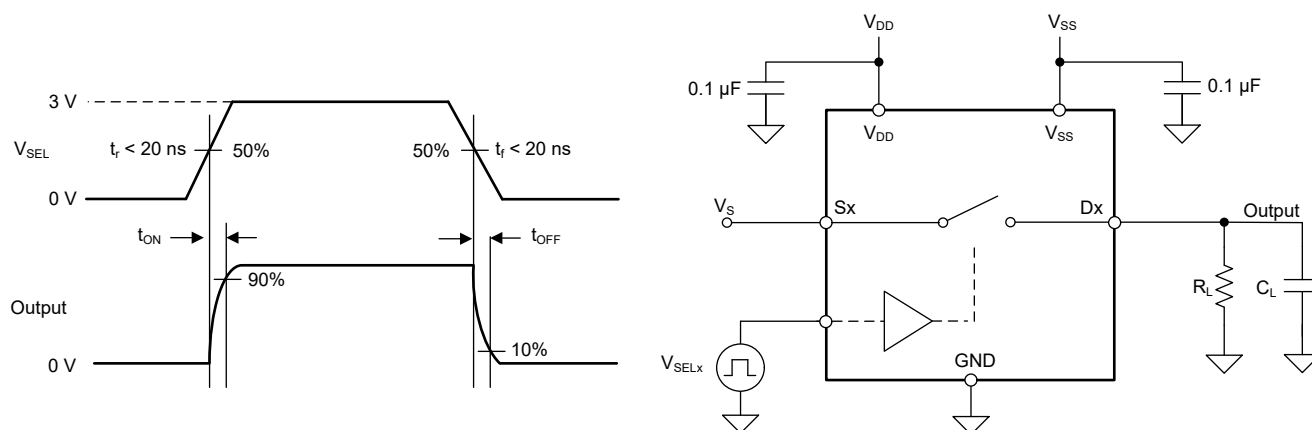


图 6-4. Turn-On and Turn-Off Time Measurement Setup

## 6.5 $t_{ON}(V_{DD})$ Time

The  $t_{ON}(V_{DD})$  time is defined as the time taken by the output of the device to rise to 90% after the supply has risen past the supply threshold. The 90% measurement is used to provide the timing of the device turning on in the system. 图 6-5 shows the setup used to measure turn on time, denoted by the symbol  $t_{ON}(V_{DD})$ .

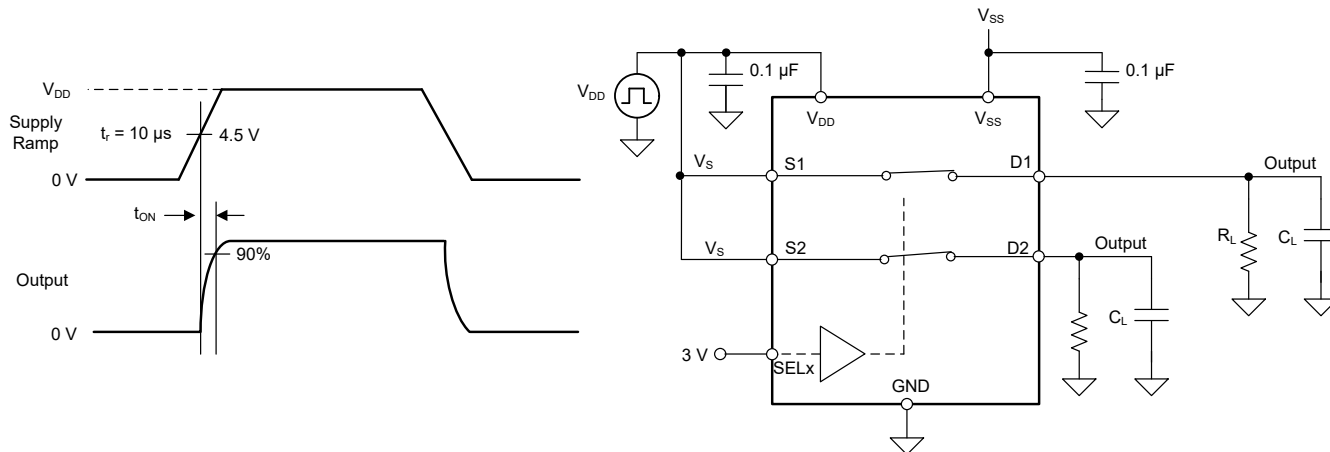


图 6-5.  $t_{ON}(V_{DD})$  Time Measurement Setup

## 6.6 Propagation Delay

Propagation delay is defined as the time taken by the output of the device to rise or fall 50% after the input signal has risen or fallen past the 50% threshold. 图 6-6 和 方程式 1 shows the setup used to measure propagation delay, denoted by the symbol  $t_{PD}$ .

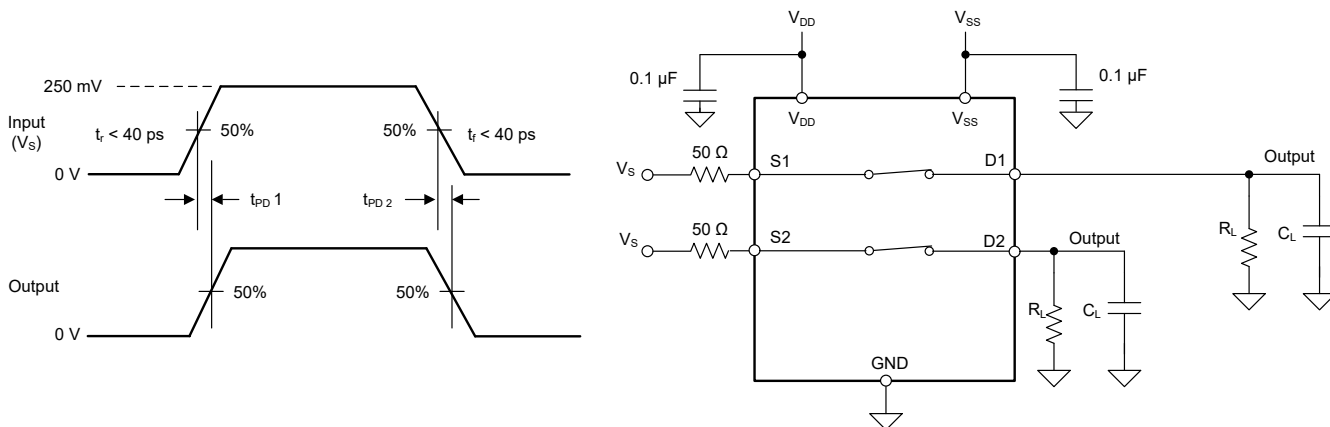


图 6-6. Propagation Delay Measurement Setup

$$t_{Prop Delay} = \max(t_{PD 1}, t_{PD 2}) \quad (1)$$

## 6.7 Charge Injection

The TMUX622x has a transmission-gate topology. Any mismatch in capacitance between the NMOS and PMOS transistors results in a charge injected into the drain or source during the falling or rising edge of the gate signal. The amount of charge injected into the source or drain of the device is known as charge injection, and is denoted by the symbol  $Q_C$ . 图 6-7 shows the setup used to measure charge injection from source ( $S_x$ ) to drain ( $D$ ).

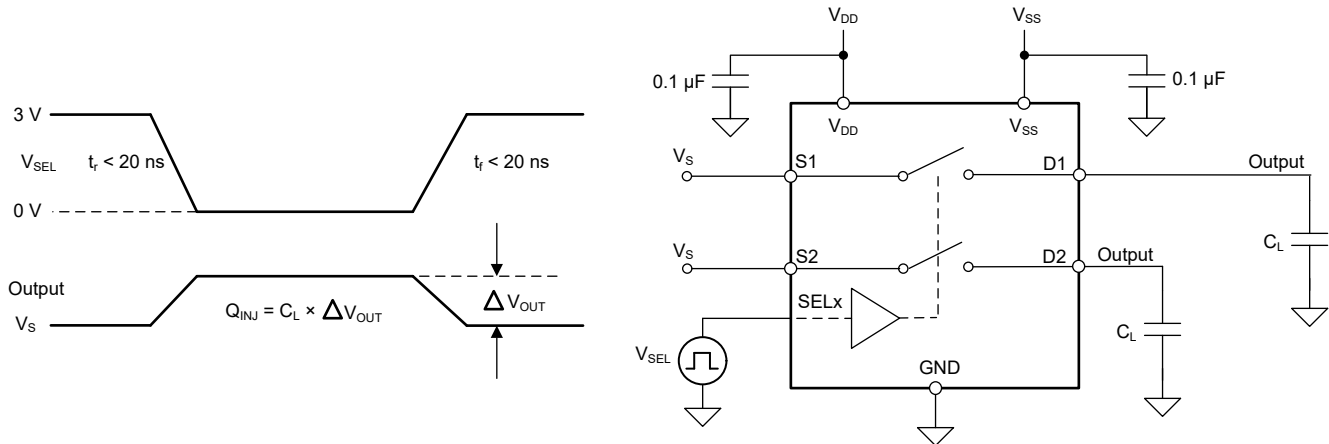


图 6-7. Charge-Injection Measurement Setup

## 6.8 Off Isolation

Off isolation is defined as the ratio of the signal at the drain pin ( $D_x$ ) of the device when a signal is applied to the source pin ( $S_x$ ) of an off-channel. The characteristic impedance,  $Z_0$ , for the measurement is  $50\ \Omega$ . 图 6-8 and 方程式 2 shows the setup used to measure off isolation. Use off isolation equation to compute off isolation.

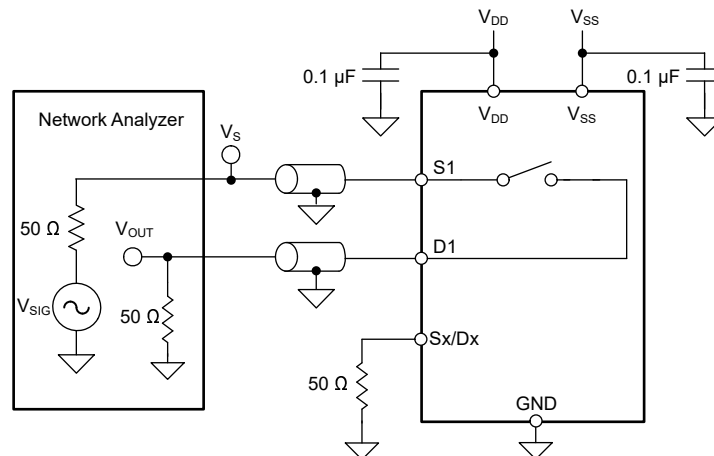


图 6-8. Off Isolation Measurement Setup

$$\text{Off Isolation} = 20 \times \text{LOG} \frac{V_{OUT}}{V_S} \quad (2)$$

## 6.9 Crosstalk

Crosstalk is defined as the ratio of the signal at the drain pin (D) of a different channel, when a signal is applied at the source pin (Sx) of an on-channel. 图 6-9 shows the setup used to measure, and 方程式 3 shows the equation used to calculate crosstalk.

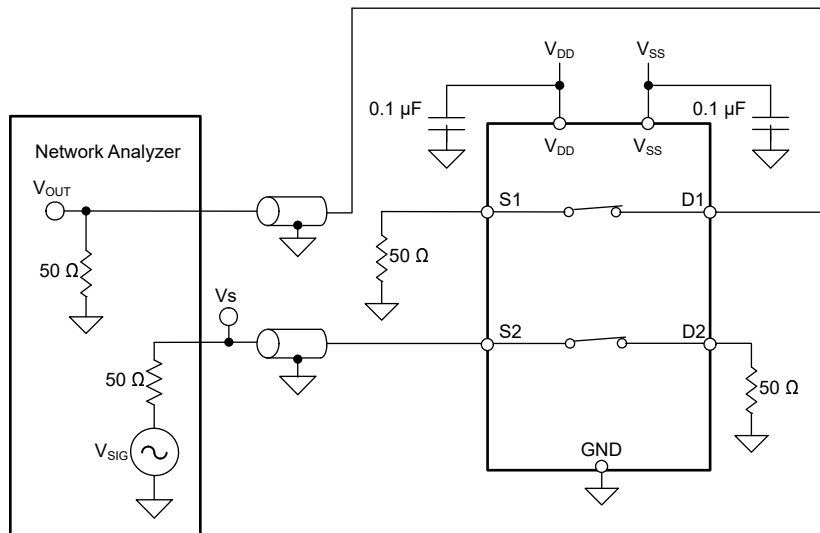


图 6-9. Crosstalk Measurement Setup

$$Crosstalk = 20 \times LOG \frac{V_{OUT}}{V_S} \quad (3)$$

## 6.10 Bandwidth

Bandwidth is defined as the range of frequencies that are attenuated by less than 3 dB when the input is applied to the source pin (Sx) of an on-channel, and the output is measured at the drain pin (Dx) of the device. The characteristic impedance,  $Z_0$ , for the measurement is 50  $\Omega$ . 图 6-10 and 方程式 4 shows the setup used to measure bandwidth.

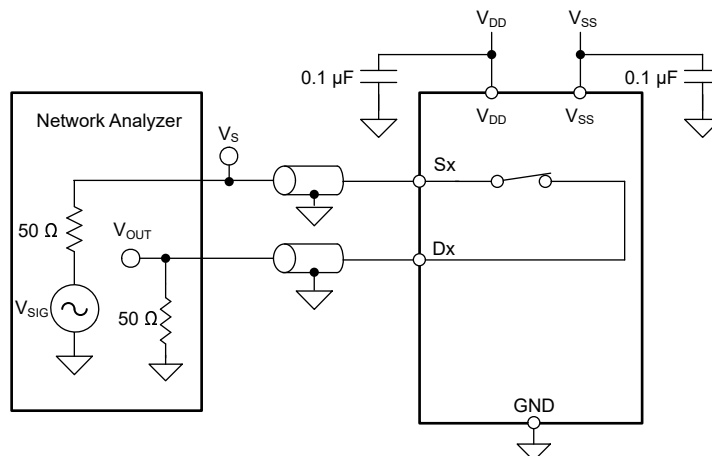


图 6-10. Bandwidth Measurement Setup

$$Bandwidth = 20 \times Log \frac{V_{OUT}}{V_S} \quad (4)$$

## 6.11 THD + Noise

The total harmonic distortion (THD) of a signal is a measurement of the harmonic distortion, and is defined as the ratio of the sum of the powers of all harmonic components to the power of the fundamental frequency at the mux output. The on-resistance of the device varies with the amplitude of the input signal and results in distortion when the drain pin is connected to a low-impedance load. Total harmonic distortion plus noise is denoted as THD + N.

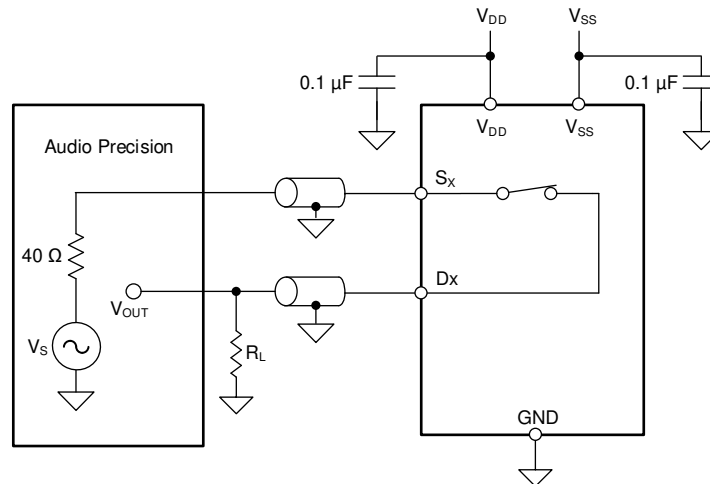


图 6-11. THD + N Measurement Setup

## 6.12 Power Supply Rejection Ratio (PSRR)

PSRR measures the ability of a device to prevent noise and spurious signals that appear on the supply voltage pin from coupling to the output of the switch. The DC voltage on the device supply is modulated by a sine wave of 100 mV<sub>PP</sub>. The ratio of the amplitude of signal on the output to the amplitude of the modulated signal is the AC PSRR.

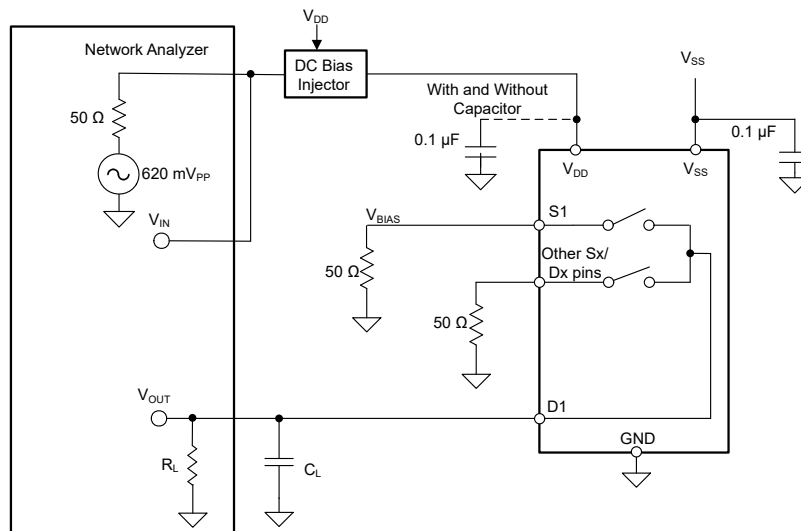


图 6-12. AC PSRR Measurement Setup

$$PSRR = 20 \times \log \frac{V_{OUT}}{V_{IN}} \quad (5)$$



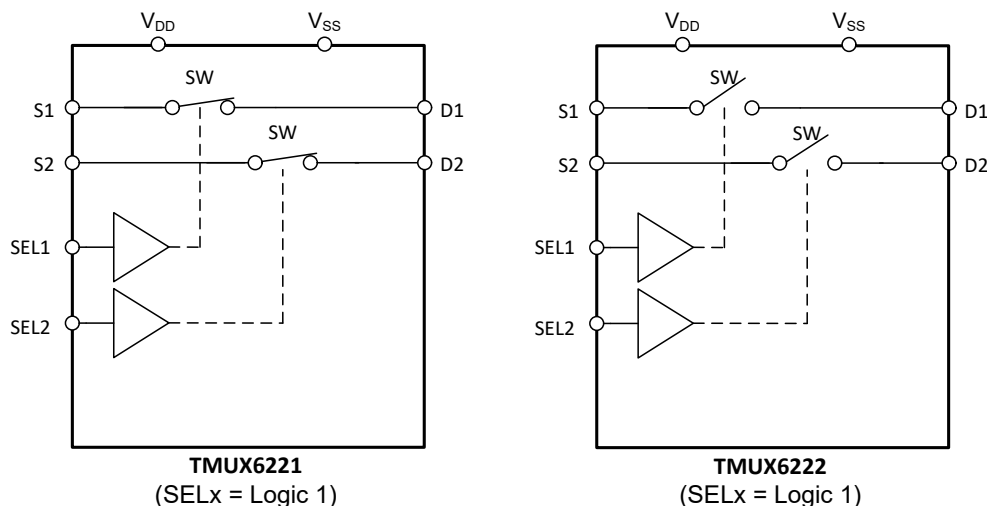
## 7 Detailed Description

### 7.1 Overview

The TMUX622x is a 1:1, 2-channel switch. Each input is turned on or turned off based on the state of the select line and enable pin.

### 7.2 Functional Block Diagram

The following figure shows the functional block diagram of the TMUX622x.



### 7.3 Feature Description

#### 7.3.1 Bidirectional Operation

The TMUX622x conducts equally well from source (Sx) to drain (D) or from drain (D) to source (Sx). Each channel has very similar characteristics in both directions and supports both analog and digital signals.

#### 7.3.2 Rail-to-Rail Operation

The valid signal path input and output voltage for TMUX622x ranges from  $V_{SS}$  to  $V_{DD}$ .

#### 7.3.3 1.8 V Logic Compatible Inputs

The TMUX622x has 1.8 V logic compatible control for all logic control inputs. 1.8 V logic level inputs allows the device to interface with processors that have lower logic I/O rails and eliminates the need for an external translator, which saves both space and BOM cost. For more information on 1.8 V logic implementations, refer to [Simplifying Design with 1.8 V logic Muxes and Switches](#).

#### 7.3.4 Integrated Pull-Down Resistor on Logic Pins

The TMUX622x have internal weak pull-down resistors to GND so that the logic pins are not left floating. The value of this pull-down resistor is approximately  $4\text{ M}\Omega$ , but is clamped to about  $1\text{ }\mu\text{A}$  at higher voltages. This feature integrates up to four external components and reduces system size and cost.

#### 7.3.5 Fail-Safe Logic

The TMUX622x supports Fail-Safe Logic on the control input pins (EN and SEL) allowing for operation up to 36 V above ground, regardless of the state of the supply pins. This feature allows voltages on the control pins to be applied before the supply pin, protecting the device from potential damage. Fail-Safe Logic minimizes system complexity by removing the need for power supply sequencing on the logic control pins. For example, the Fail-Safe Logic feature allows the logic input pins of the TMUX622x to be ramped to +36 V while  $V_{DD}$  and  $V_{SS} = 0\text{ V}$ . The logic control inputs are protected against positive faults of up to +36 V in powered-off condition, but do not offer protection against negative overvoltage conditions.

### 7.3.6 Latch-Up Immune

Latch-up is a condition where a low impedance path is created between a supply pin and ground. This condition is caused by a trigger (current injection or overvoltage), but once activated, the low impedance path remains even after the trigger is no longer present. This low impedance path may cause system upset or catastrophic damage due to excessive current levels. The latch-up condition typically requires a power cycle to eliminate the low impedance path.

The TMUX622x family of devices are constructed on silicon-on-insulator (SOI) based process where an oxide layer is added between the PMOS and NMOS transistor of each CMOS switch to prevent parasitic structures from forming. The oxide layer is also known as an insulating trench and prevents triggering of latch up events due to overvoltage or current injections. The latch-up immunity feature allows the TMUX622x family of switches and multiplexers to be used in harsh environments.

### 7.3.7 Ultra-Low Charge Injection

The TMUX622x has a transmission gate topology, as shown in 图 7-1. Any mismatch in the stray capacitance associated with the NMOS and PMOS causes an output level change whenever the switch is opened or closed.

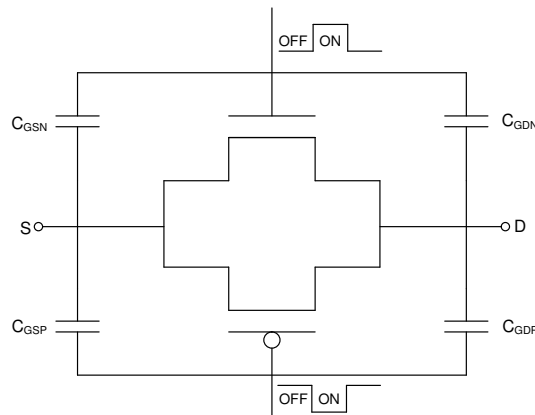


图 7-1. Transmission Gate Topology

The TMUX622x contains specialized architecture to reduce charge injection on the Drain (Dx). To further reduce charge injection in a sensitive application, a compensation capacitor ( $C_p$ ) can be added on the Source (Sx). Doing this will push excess charge from the switch transition into the compensation capacitor on the Source (Sx) instead of the Drain (Dx). As a general rule,  $C_p$  should be 20x larger than the equivalent load capacitance on the Drain (Dx). 图 7-2 shows charge injection variation with different compensation capacitors on the Source side. This plot was captured on the TMUX6219 as part of the TMUX62xx family with a 100 pF load capacitance.

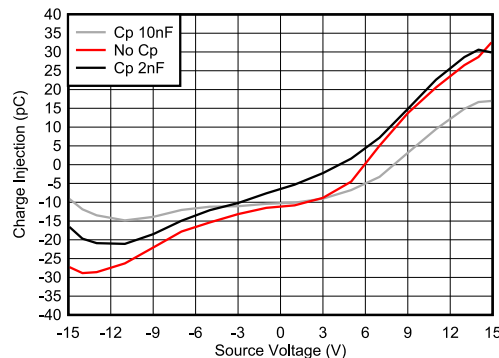


图 7-2. Charge Injection Compensation

## 7.4 Device Functional Modes

The TMUX622x devices have two independently selectable single-pole, single-throw switches that are turned-on or turned-off based on the state of the corresponding select pin. The control pins can be as high as 36 V.

The TMUX622x devices can be operated without any external components except for the supply decoupling capacitors. The SEL pins has internal pull-down resistor of 4 M $\Omega$ . If unused, tie the SEL pins to GND so that the device does not consume additional current. For more information, see [Implications of Slow or Floating CMOS Inputs](#). Unused signal path inputs (S1, S2, D1, or D2) should be connected to GND.

## 7.5 Truth Tables

表 7-1 provides the truth tables for the TMUX622x.

表 7-1. TMUX6221 Truth Table

| SEL x | CHANNEL x     |
|-------|---------------|
| 0     | Channel x OFF |
| 1     | Channel x ON  |

表 7-2. TMUX6222 Truth Table

| SEL x | CHANNEL x     |
|-------|---------------|
| 0     | Channel x ON  |
| 1     | Channel x OFF |

## 8 Application and Implementation

### 备注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Application Information

TMUX622x is part of the precision switches and multiplexers family of devices. TMUX622x offers low  $R_{ON}$ , low on and off leakage currents and ultra-low charge injection performance. These properties make TMUX622x ideal for implementing high precision industrial systems requiring selection of one of two inputs or outputs.

### 8.2 Typical Applications

#### 8.2.1 Switched Gain Amplifier – Discrete PGA

Switches and multiplexers are commonly used in the feedback path of the amplifier circuits to provide configurable gain control. By using various resistor values on each switch path, the TMUX622x allows the system to have multiple gain settings. An external resistor causes the amplifier to not operate in an open loop configuration and gives up to 4 gain settings. The leakage current, on-resistance, and charge injection performance of the TMUX622x are key specifications to evaluate when selecting a device for gain control.

图 8-1 shows the TMUX622x configured to select the gain of an op-amp, creating a discrete PGA.

For more information on how to use TI's analog switches in Discrete Programmable Gain Amplifier (PGA) such as the impact of On-Capacitance, see [Choosing the Right Multiplexer for a Discrete Programmable Gain Amplifier \(PGA\)](#)

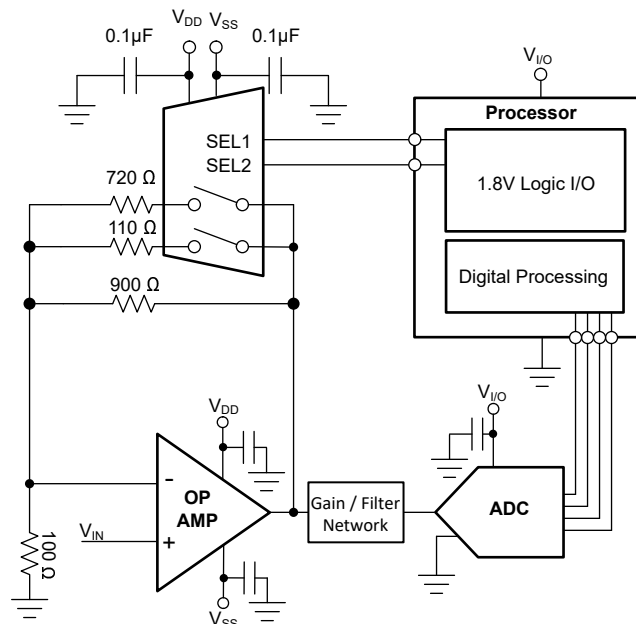


图 8-1. Gain Switching

### 8.2.1.1 Design Requirements

For this design example, use the parameters listed in 表 8-1.

表 8-1. Design Parameters

| PARAMETERS                   | VALUES                       |
|------------------------------|------------------------------|
| Supply ( $V_{DD}$ )          | 15 V                         |
| Supply ( $V_{SS}$ )          | -15 V                        |
| Input or output signal range | -15 V to 15 V (Rail-to-Rail) |
| Control logic thresholds     | 1.8 V compatible             |

### 8.2.1.2 Detailed Design Procedure

The TMUX622x device can operate without any external components except for the supply decoupling capacitors. All inputs signals passing through the switch must fall within the recommend operating conditions of the TMUX622x including signal range and continuous current. For this design example, with a supply of +15 V and -15 V, the signals can range from +15 V to -15 V when the device is powered.

The application shown in [Switching Gain Settings](#) demonstrates how to use the TMUX622x to control the feedback gain of a precision op-amp. This feedback design can very sensitive to induced voltage and current offsets. The TMUX622x has a typical on-leakage current of 100 pA which would lead to an accuracy well within 1% of a full scale 1  $\mu$ A signal, thus minimizing errors from current offsets. The low on-resistance of the TMUX622x leads to a low error in the feedback resistance and resulting gain. This additionally minimizes any voltage offsets.

表 8-2. Programmable Gain and Error

| SEL1 | SEL2 | Gain | Gain Error |
|------|------|------|------------|
| 0    | 0    | 10x  | 0%         |
| 1    | 0    | 5x   | 0.13%      |
| 0    | 1    | 2x   | 0.16%      |

### 8.2.1.3 Application Curves

The TMUX622x is capable of switching signals with minimal distortion because of the ultra-low leakage currents and excellent on-resistance flatness. 图 8-2 shows how the on-resistance for the TMUX622x varies with different supply voltages.

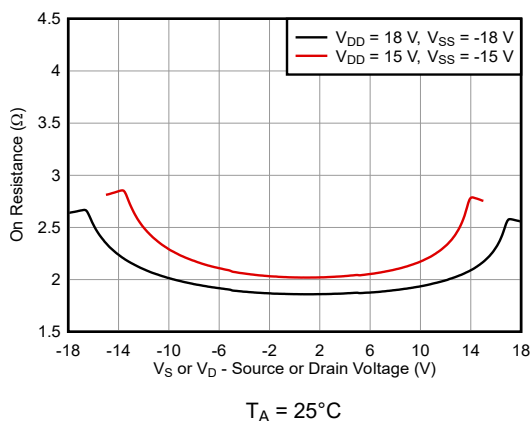


图 8-2. On-Resistance vs Source or Drain Voltage

### 8.3 Power Supply Recommendations

The TMUX622x operates across a wide supply range of  $\pm 4.5\text{ V}$  to  $\pm 18\text{ V}$  (4.5 V to 36 V in single-supply mode). The device also performs well with asymmetrical supplies such as  $V_{DD} = 12\text{ V}$  and  $V_{SS} = -5\text{ V}$ .

Power-supply bypassing improves noise margin and prevents switching noise propagation from the supply rails to other components. Good power-supply decoupling is important to achieve optimum performance. For improved supply noise immunity, use a supply decoupling capacitor ranging from  $0.1\text{ }\mu\text{F}$  to  $10\text{ }\mu\text{F}$  at both the  $V_{DD}$  and  $V_{SS}$  pins to ground. Place the bypass capacitors as close to the power supply pins of the device as possible using low-impedance connections. TI recommends using multi-layer ceramic chip capacitors (MLCCs) that offer low equivalent series resistance (ESR) and inductance (ESL) characteristics for power-supply decoupling purposes. For very sensitive systems, or for systems in harsh noise environments, avoiding the use of vias for connecting the capacitors to the device pins may offer superior noise immunity. The use of multiple vias in parallel lowers the overall inductance and is beneficial for connections to ground and power planes. Always ensure the ground (GND) connection is established before supplies are ramped.

## 8.4 Layout

### 8.4.1 Layout Guidelines

When a PCB trace turns a corner at a  $90^\circ$  angle, a reflection can occur. A reflection occurs primarily because of the change of width of the trace. At the apex of the turn, the trace width increases to 1.414 times the width. This increase upsets the transmission-line characteristics, especially the distributed capacitance and self-inductance of the trace which results in the reflection. Not all PCB traces can be straight and therefore some traces must turn corners. 图 8-3 shows progressively better techniques of rounding corners. Only the last example (BEST) maintains constant trace width and minimizes reflections.

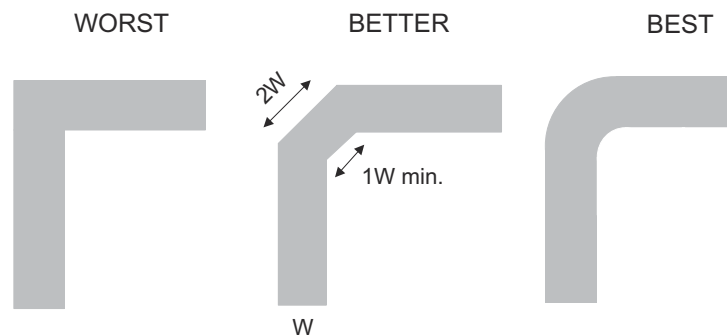


图 8-3. Trace Example

Route high-speed signals using a minimum of vias and corners which reduces signal reflections and impedance changes. When a via must be used, increase the clearance size around it to minimize its capacitance. Each via introduces discontinuities in the signal's transmission line and increases the chance of picking up interference from the other layers of the board. Be careful when designing test points, through-hole pins are not recommended at high frequencies.

Some key considerations are:

- For reliable operation, connect a decoupling capacitor ranging from  $0.1\text{ }\mu\text{F}$  to  $10\text{ }\mu\text{F}$  between  $V_{DD}/V_{SS}$  and GND. We recommend a  $0.1\text{ }\mu\text{F}$  and  $1\text{ }\mu\text{F}$  capacitor, placing the lowest value capacitor as close to the pin as possible. Make sure that the capacitor voltage rating is sufficient for the supply voltage.
- Keep the input lines as short as possible.
- Use a solid ground plane to help reduce electromagnetic interference (EMI) noise pickup.
- Do not run sensitive analog traces in parallel with digital traces. Avoid crossing digital and analog traces if possible, and only make perpendicular crossings when necessary.
- Using multiple vias in parallel will lower the overall inductance and is beneficial for connection to ground planes.

### 8.4.2 Layout Example

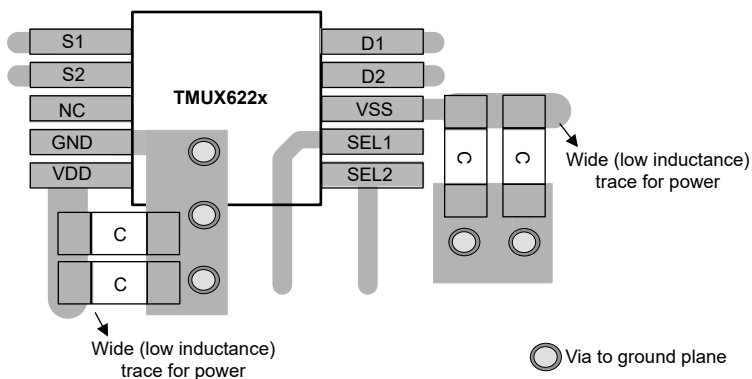


图 8-4. TMUX622x Layout Example

## 9 Device and Documentation Support

### 9.1 Documentation Support

#### 9.1.1 Related Documentation

- Texas Instruments, [Improve Stability Issues with Low CON Multiplexers](#).
- Texas Instruments, [Improving Signal Measurement Accuracy in Automated Test Equipment](#).
- Texas Instruments, [Multiplexers and Signal Switches Glossary](#).
- Texas Instruments, [QFN/SON PCB Attachment](#).
- Texas Instruments, [Quad Flat pack No-Lead Logic Packages](#).
- Texas Instruments, [Simplifying Design with 1.8 V logic Muxes and Switches](#).
- Texas Instruments, [System-Level Protection for High-Voltage Analog Multiplexers](#).
- Texas Instruments, [True Differential, 4 x 2 MUX, Analog Front End, Simultaneous-Sampling ADC Circuit](#).

### 9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 9.3 支持资源

TI E2E™ 中文支持论坛是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的[使用条款](#)。

### 9.4 Trademarks

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ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

### 9.6 术语表

TI 术语表 本术语表列出并解释了术语、首字母缩略词和定义。

## 10 Revision History

注：以前版本的页码可能与当前版本的页码不同

#### Changes from Revision A (September 2023) to Revision B (May 2024) Page

- Updated the *Pin Configuration* section to accurately reflect the correct pin number for SEL1 and SEL2.....3

#### Changes from Revision \* (March 2023) to Revision A (September 2023) Page

- 将数据表的状态从 *预告信息* 更改为 *量产数据* .....1



## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable part number        | Status<br>(1) | Material type<br>(2) | Package   Pins   | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|------------------------------|---------------|----------------------|------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">TMUX6221DGSR</a> | Active        | Production           | VSSOP (DGS)   10 | 2500   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | TM221               |
| TMUX6221DGSR.B               | Active        | Production           | VSSOP (DGS)   10 | 2500   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | TM221               |
| <a href="#">TMUX6222DGSR</a> | Active        | Production           | VSSOP (DGS)   10 | 2500   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | TM222               |
| TMUX6222DGSR.B               | Active        | Production           | VSSOP (DGS)   10 | 2500   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | TM222               |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TMUX6221DGSR | VSSOP        | DGS             | 10   | 2500 | 330.0              | 12.4               | 5.25    | 3.35    | 1.25    | 8.0     | 12.0   | Q1            |
| TMUX6222DGSR | VSSOP        | DGS             | 10   | 2500 | 330.0              | 12.4               | 5.25    | 3.35    | 1.25    | 8.0     | 12.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TMUX6221DGSR | VSSOP        | DGS             | 10   | 2500 | 366.0       | 364.0      | 50.0        |
| TMUX6222DGSR | VSSOP        | DGS             | 10   | 2500 | 366.0       | 364.0      | 50.0        |

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